








Review Approval



-  Prepare Request
-  **Search Requests**
-  Generate Reports
-  Approvals
-  Help
-  Wizard

-  Search Requests
- [New Search](#)
- [Refine Search](#)
- [Search Results](#)
-
- [Clone Request](#)
- [Edit Request](#)
- [Cancel Request](#)

Search Detail

Submittal Details

Document Info

Title : Quantum Dot Cellular Automata (QDCA) Strategic Partnership: Extending Moore's Law -- Part 1, Physical Sciences Issues
Document Number : 5245420 **SAND Number :** 2006-5383 P
Review Type : Electronic **Status :** Approved
Sandia Contact : [DEBENEDICTIS,ERIK P.](#) **Submittal Type :** Viewgraph/Presentation
Requestor : [DEBENEDICTIS,ERIK P.](#) **Submit Date :** 08/18/2006
Comments : Jointly prepared presentation documenting a LDRD strategic partnership.
Peer Reviewed? : N

Author(s)

Craig Lent	DEBENEDICTIS,ERIK P.	Greg Snider
Jerry Floro	Marco Ottavi	Mike Niemier
MURPHY,SARAH	Peter Kogge	PRAGER,AARON A.
Robert Hull		

Event (Conference/Journal/Book) Info

Name : Seminar on QDCA
City : Albuquerque **State :** NM **Country :** USA
Start Date : 08/01/2006 **End Date :** 08/01/2006

Partnership Info

Partnership Involved : No
Partner Approval : **Agreement Number :**

Patent Info

Scientific or Technical in Content : Yes
Technical Advance : No **TA Form Filed :** No
SD Number :

Classification and Sensitivity Info

Title : Unclassified-Unlimited **Abstract :** **Document :** Unclassified-Unlimited
Additional Limited Release Info : None.
DUSA : None.

Routing Details

Role	Routed To	Approved By	Approval Date
Derivative Classifier Approver	AIDUN,JOHN B.	AIDUN,JOHN B.	08/22/2006
Conditions:			
Classification Approver	WILLIAMS,RONALD L.	WILLIAMS,RONALD L.	08/28/2006
Conditions:			
Manager Approver	PUNDIT,NEIL D.	PUNDIT,NEIL D.	08/30/2006
Conditions:	1. The Title should spell out "- Part 1, Physical Sciences Issues" 2. This needs endorsement from a subject matter expert. Lyndon Pierson is being approached for the purpose.		
Sandia Contact	DEBENEDICTIS,ERIK P.	DEBENEDICTIS,ERIK P.	08/30/2006
Agreement: Sandia Contact has agreed to incorporate above listed conditions prior to release.			
Comments:			

Administrator Approver LUCERO, ARLENE M.

Created by WebCo Problems? Contact CCHD: **by email** or **at 845-CCHD (2243)**.

For Review and Approval process questions please contact the **Application Process Owner**



Quantum Dot Cellular Automata (QDCA) Strategic Partnership: Extending Moore's Law: Part 1, Physical Sciences Issues

**Erik DeBenedictis¹ (PI), Jerry Floro^{1,3},
Robert Hull³, Peter Kogge², Craig Lent²,
Sarah Murphy^{1,2}, Mike Niemier², Marco
Ottavi¹, Aaron Prager^{1,2}, Greg Snider²
(¹Sandia, ²Notre Dame, ³U. Virginia)**

SAND2006-5383P

Approved for Unclassified Unlimited Release



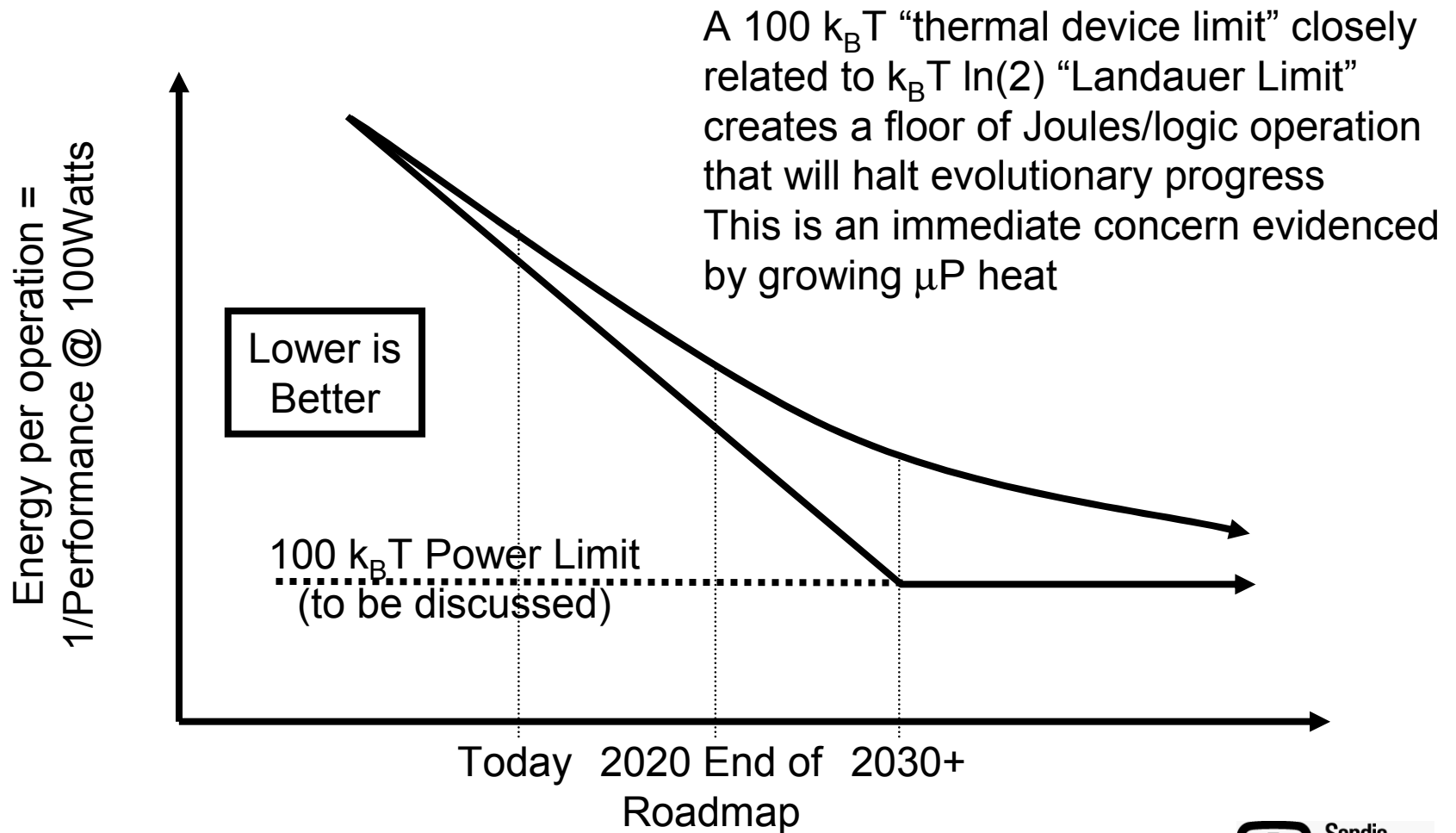


Experiments Under Discussion

- **Continuation of Quantum Fortress work 1100**
- **Molecular QCA 1800**
- **Quantum Computing Tie-In**
 - **Architecture**
 - **Quantum Dot Measurements**
 - **Quantum Dot Manufacturing classical/quantum**
- **Computer Architecture beyond limits of Moore's Law**
- **Simulation of information+Physics**



Moore's Law for Logic Switching Power





Emerging Research Devices (notes 2005)

- Table shows drop in replacements for CMOS transistors that defeat limit in previous slide
- Color code: **OK**, **marginal**, **unacceptable**
- **CNFET** on table only for political reasons

Logic Device Technologies	Scalability	Performance	Energy Efficiency	Gain	Operational Reliability	Room Temp. Operation ***	CMOS Compatibility **	CMOS Architectural Compatibility *
1D Structures	2.4	2.4	2.1	2.4	2.3	2.9	2.4	2.6
Resonant Tunneling Devices	1.4	2.0	1.9	1.7	1.7	2.9	2.1	2.1
SETs	1.9	1.0	2.5	1.3	1.2	1.9	2.4	2.0
Molecular Devices	1.9	1.1	2.0	1.1	1.3	2.6	1.9	1.6
Ferromagnetic Devices	1.5	1.2	1.8	1.5	1.8	2.2	1.5	1.8
Spin Transistor	1.7	1.7	2.2	1.5	2.0	2.2	1.7	1.8

> 20

>16 - 18

>18 - 20

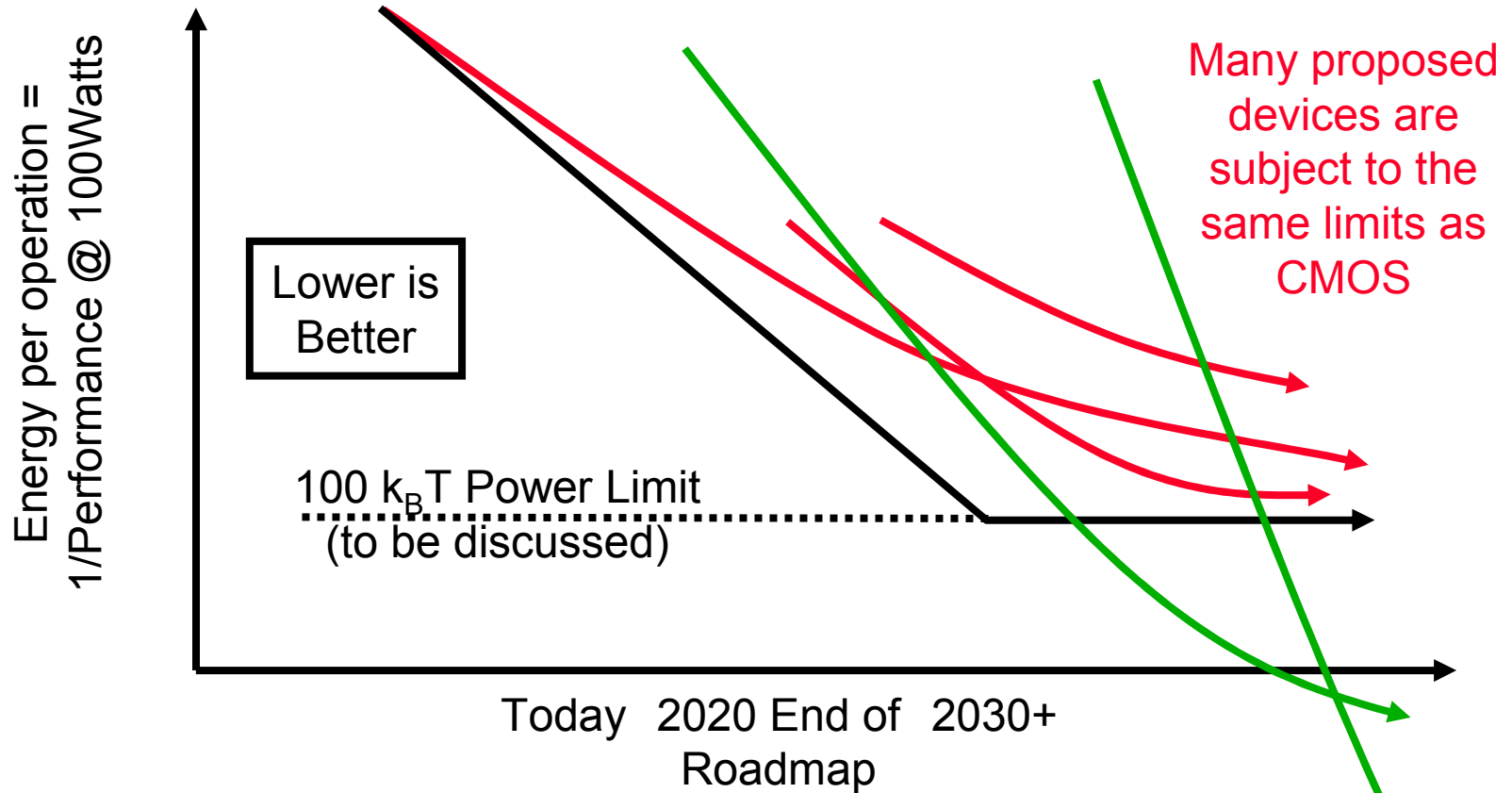
< 16

For each Technology Entry (e.g. 1D Structures, sum horizontally over the 8 Criteria
 Max Sum = 24
 Min Sum = 8

Evaluation of Emerging Research Logic Device Technologies against Technology Evaluation Criteria



Obeying Moore's Law and Beating CMOS



This project addresses approaches that can decisively beat CMOS at the end of the roadmap: Principal concepts: Reversible Logic and Quantum Computing



Tie Between Information and Device Physics

- **We use Boolean logic today, based on AND-OR-NOT**
- **AND and OR gates “destroy” information, which creates heat irrespective of physical implementation (to be described later)**
- **This limit can be circumvented by a different form of logic that does not “destroy” information**
- **However, this will also require different devices...**



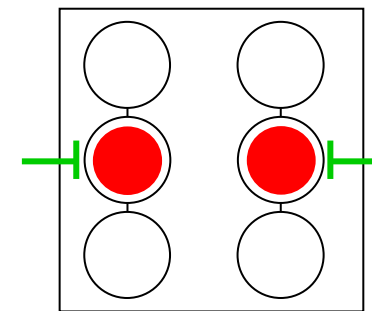
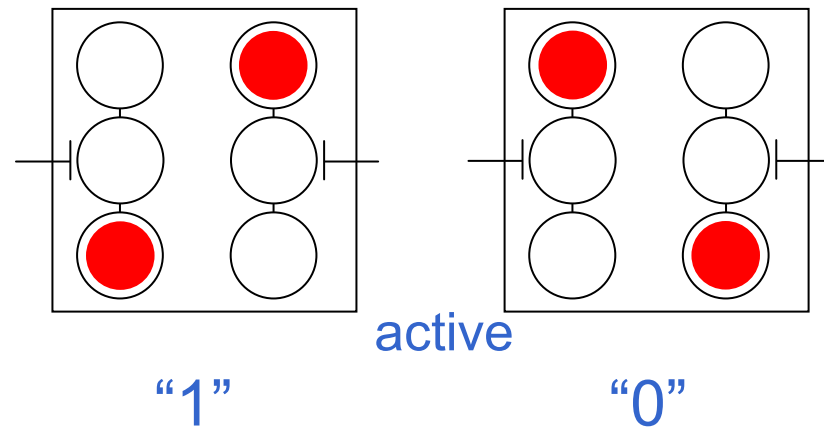
Quantum-dot cellular automata

Represent binary information by charge configuration of cell.

QCA cell

- Dots localize charge
- Two mobile charges
- Tunneling between dots
- Clock signal varies relative energies of “active” and “null” dots

Clock need not separately contact each cell.



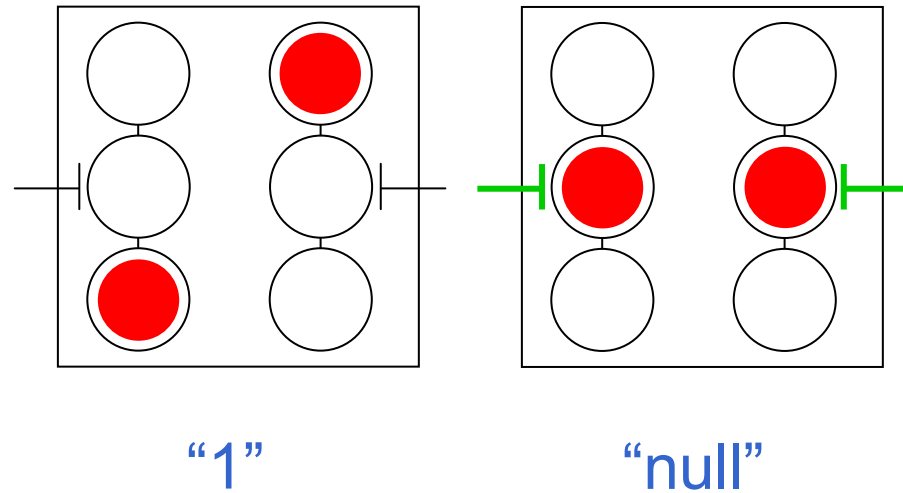
“null”





Quantum-dot cellular automata

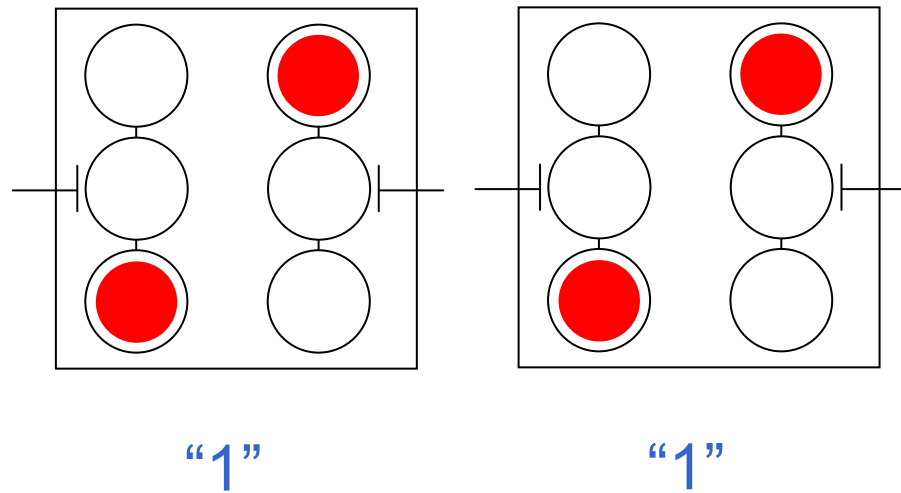
Neighboring cells tend to align in the same state.





Quantum-dot cellular automata

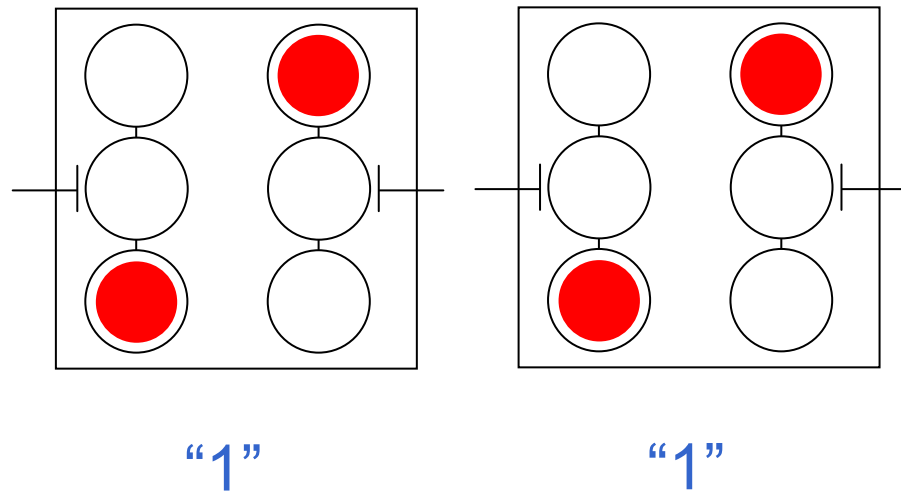
Neighboring cells tend to align in the same state.





Quantum-dot cellular automata

Neighboring cells tend to align in the same state.

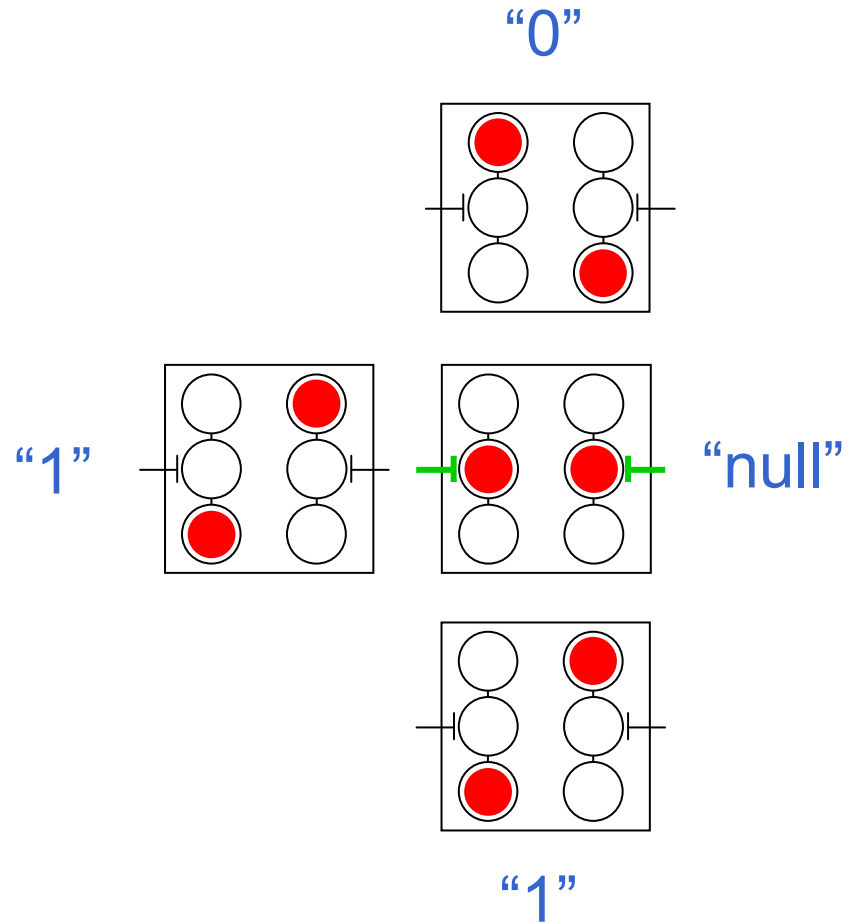


This is the COPY operation.



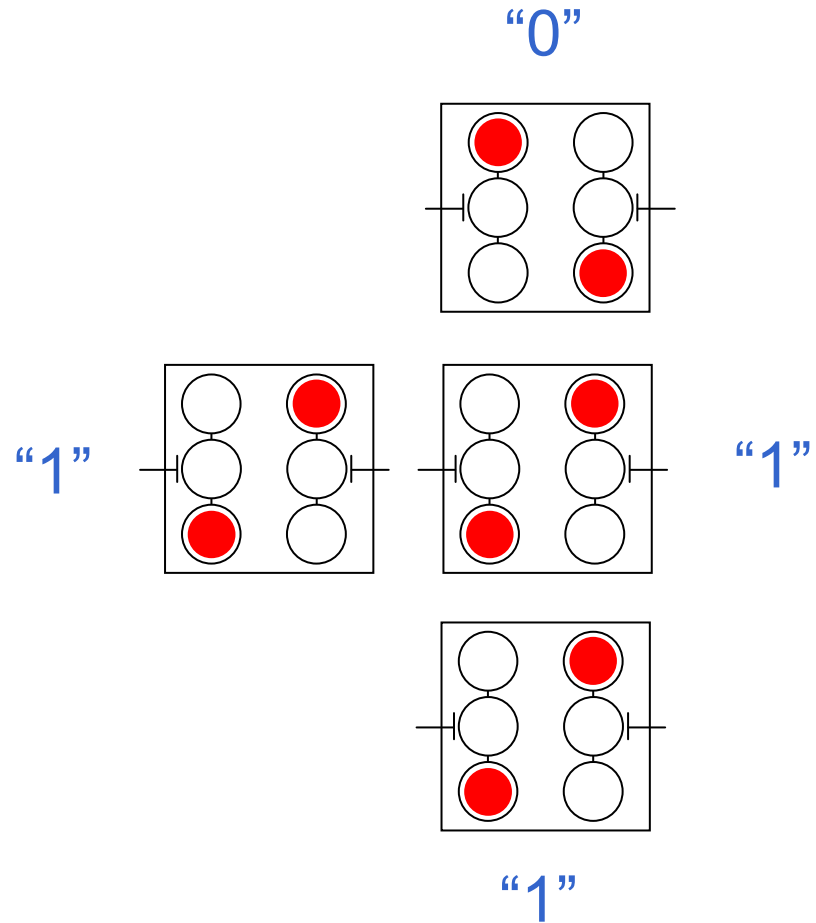


Majority Gate





Majority Gate

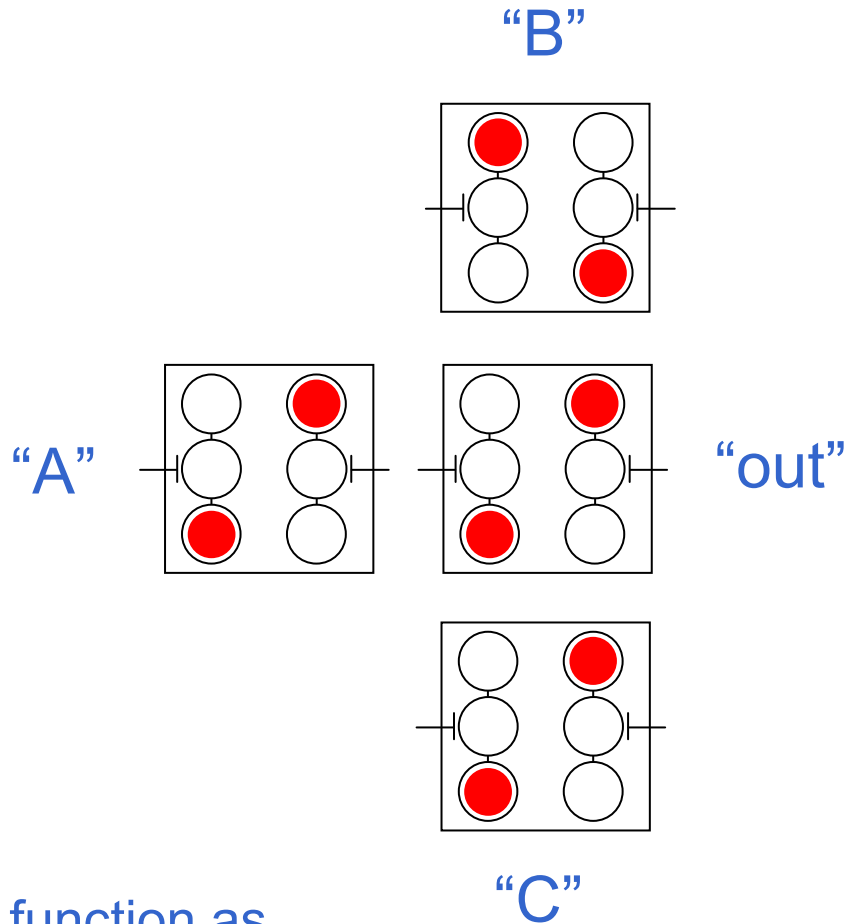




Majority Gate



	A	B	C	Output
AND gate	0	0	0	0
	0	0	1	0
	0	1	1	1
	0	1	0	0
OR gate	1	1	0	1
	1	1	1	1
	1	0	1	1
	1	0	0	0

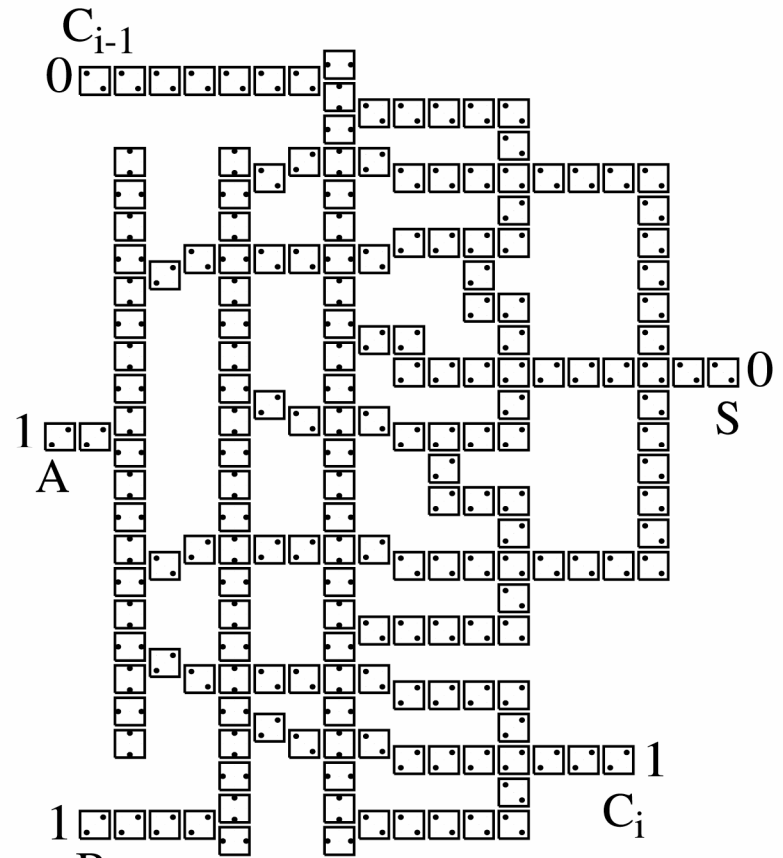
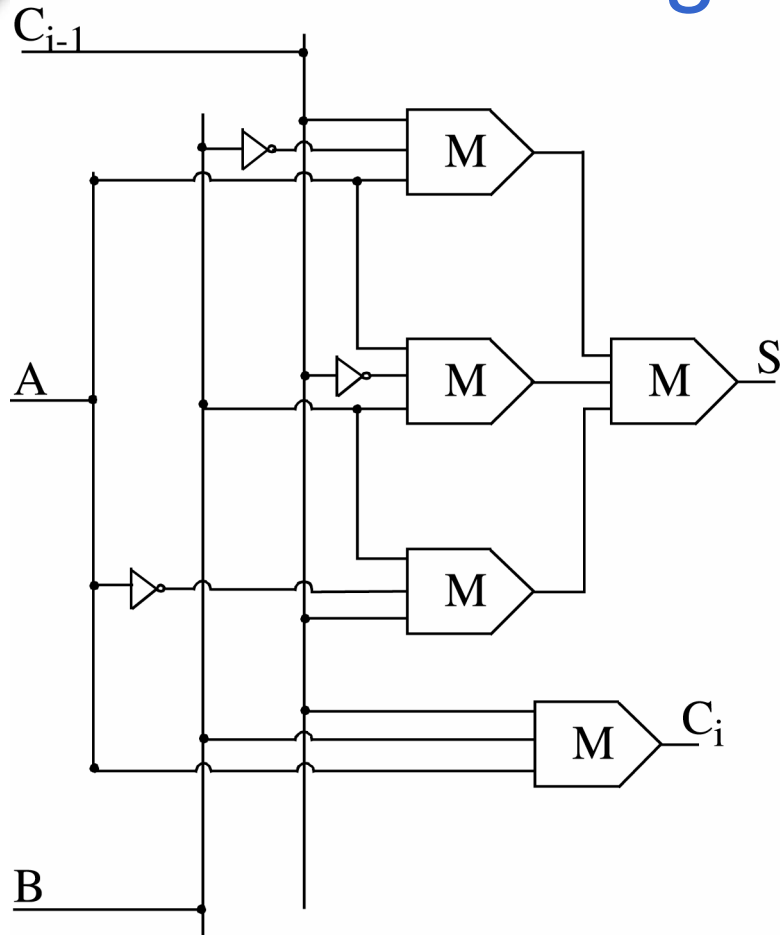


Three input majority gate can function as programmable 2-input AND/OR gate.





QCA single-bit full adder



result of SC-HF calculation
with site model

Hierarchical layout and design are possible.
Simple-12 microprocessor (Kogge & Niemier)



Notre Dame
Center for Nano Science
and Technology





Computational wave: adder back-end

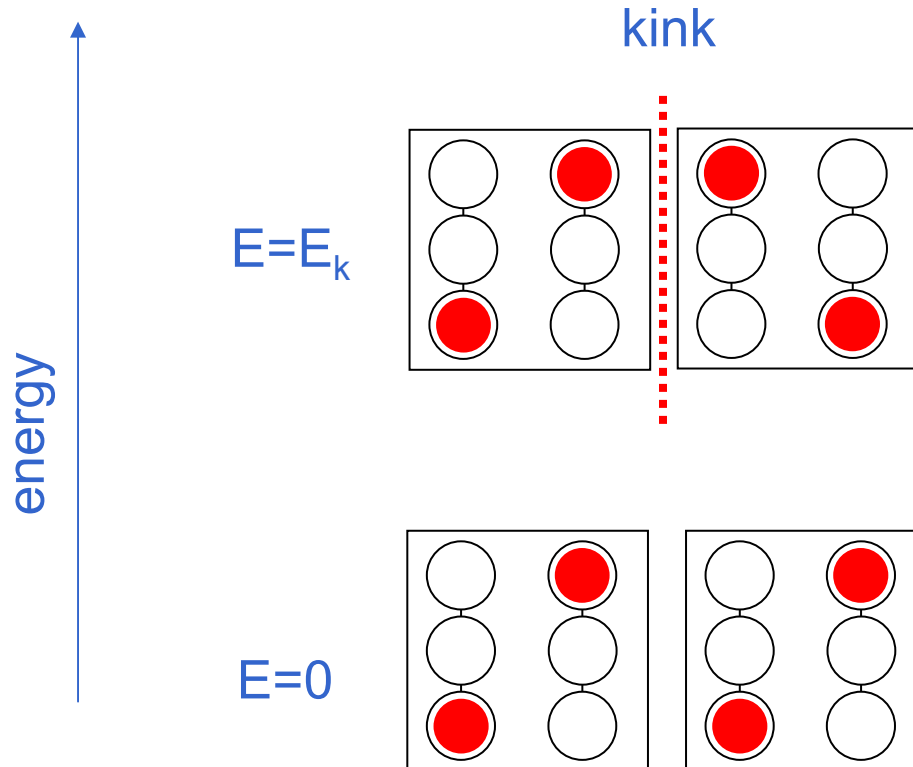


Notre Dame
Center for Nano Science
and Technology





Characteristic energy

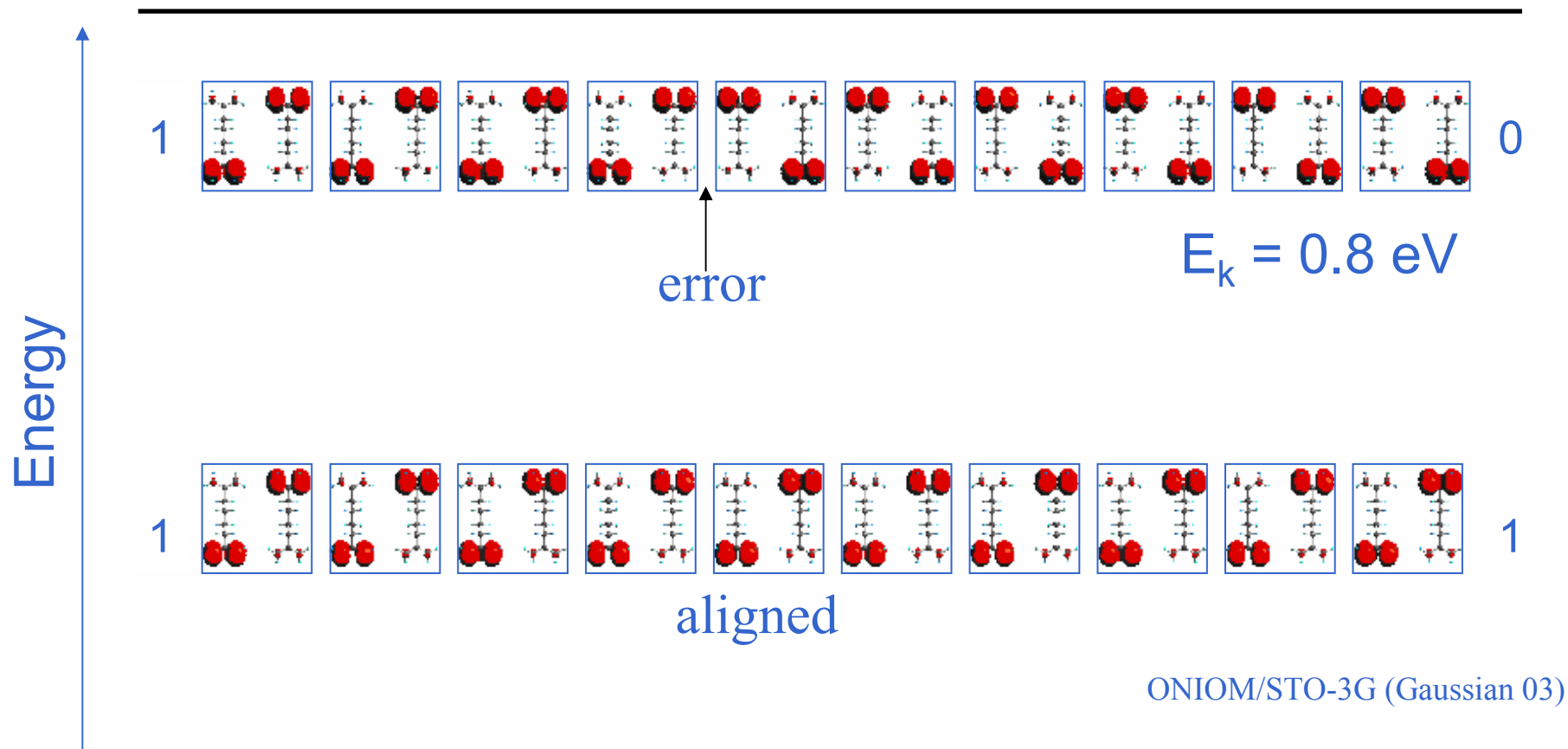


We would like “kink energy” $E_k > k_B T$.





Molecular Wire





Power Gain in QCA Cells

- Power gain is crucial for practical devices because some energy is always lost between stages.
- Lost energy must be replaced.
 - Conventional devices – current from power supply
 - QCA devices – from the clock
- Unity power gain means replacing exactly as much energy as is lost to environment.

Power gain > 3 has been measured in metal-dot QCA.





Landauer Clocking

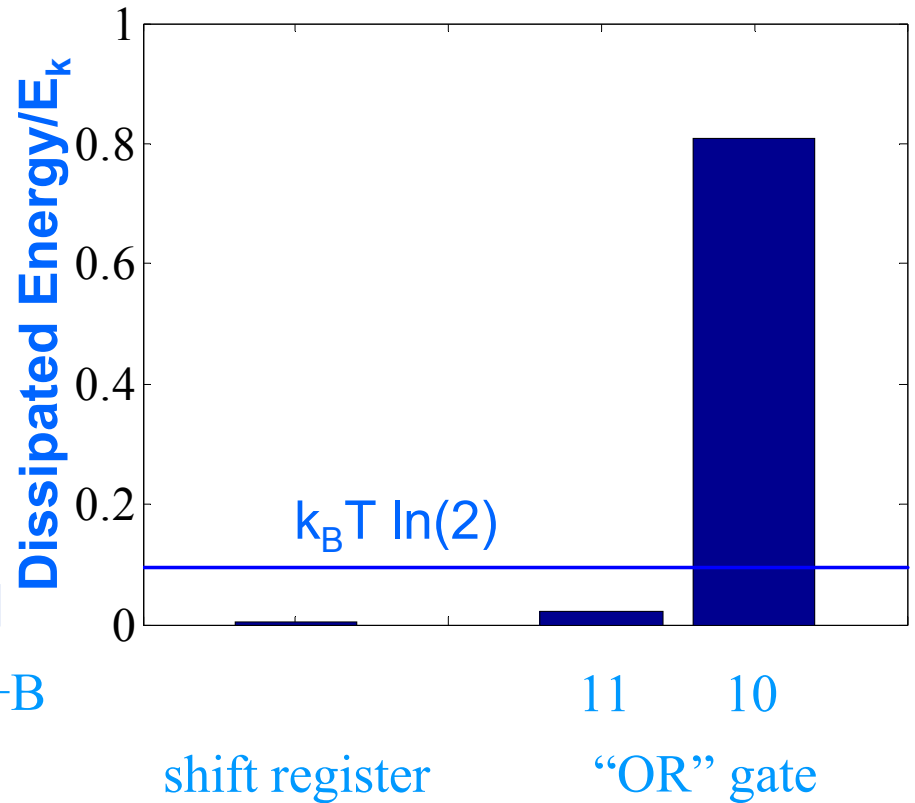
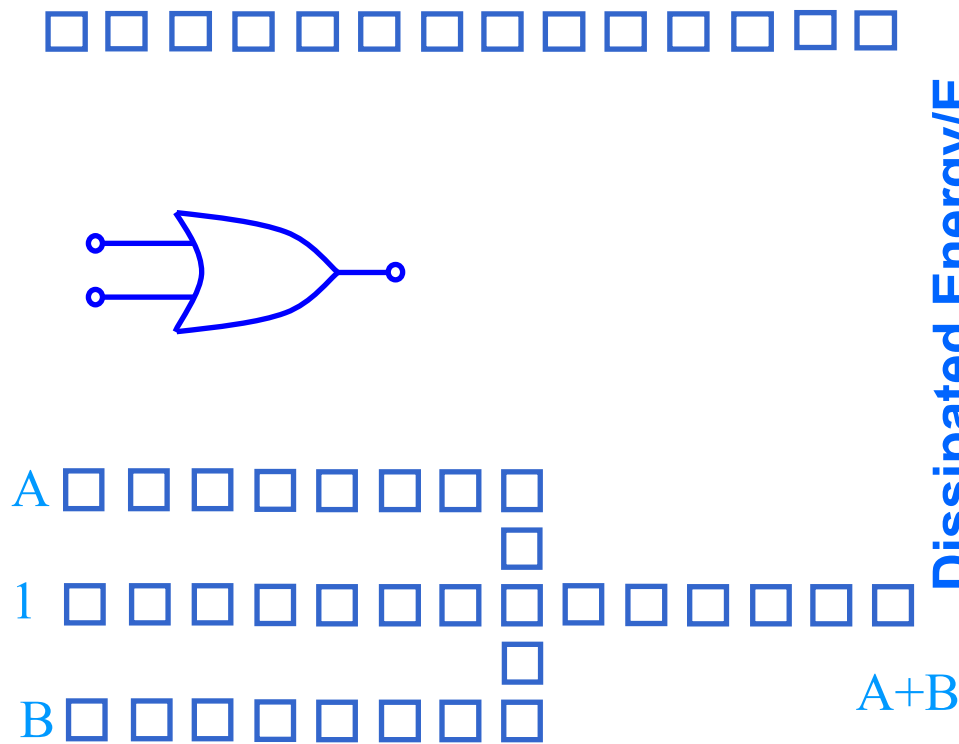


Notre Dame
Center for Nano Science
and Technology



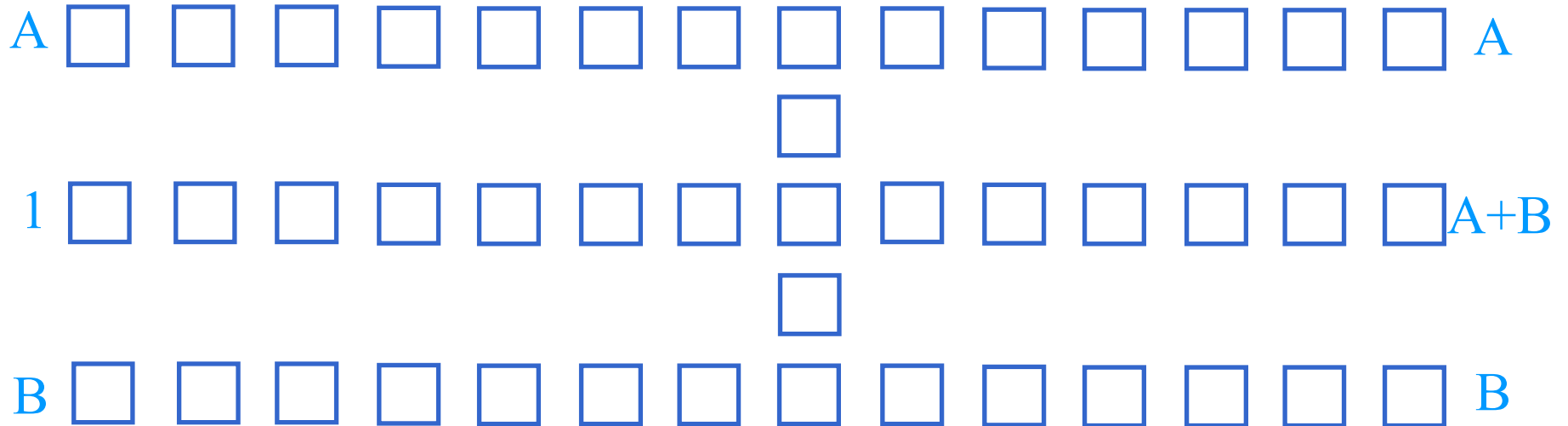
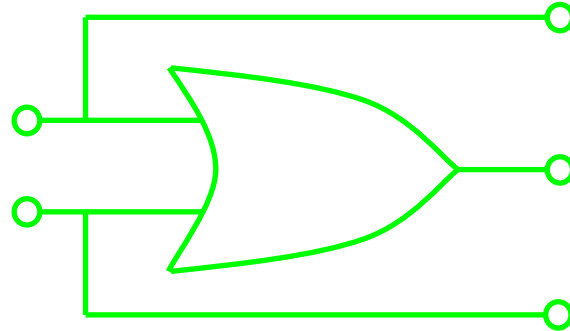


Energy dissipation in Landauer-clocked circuit





Test circuit: OR gate



Landauer clocking with echo of inputs to outputs

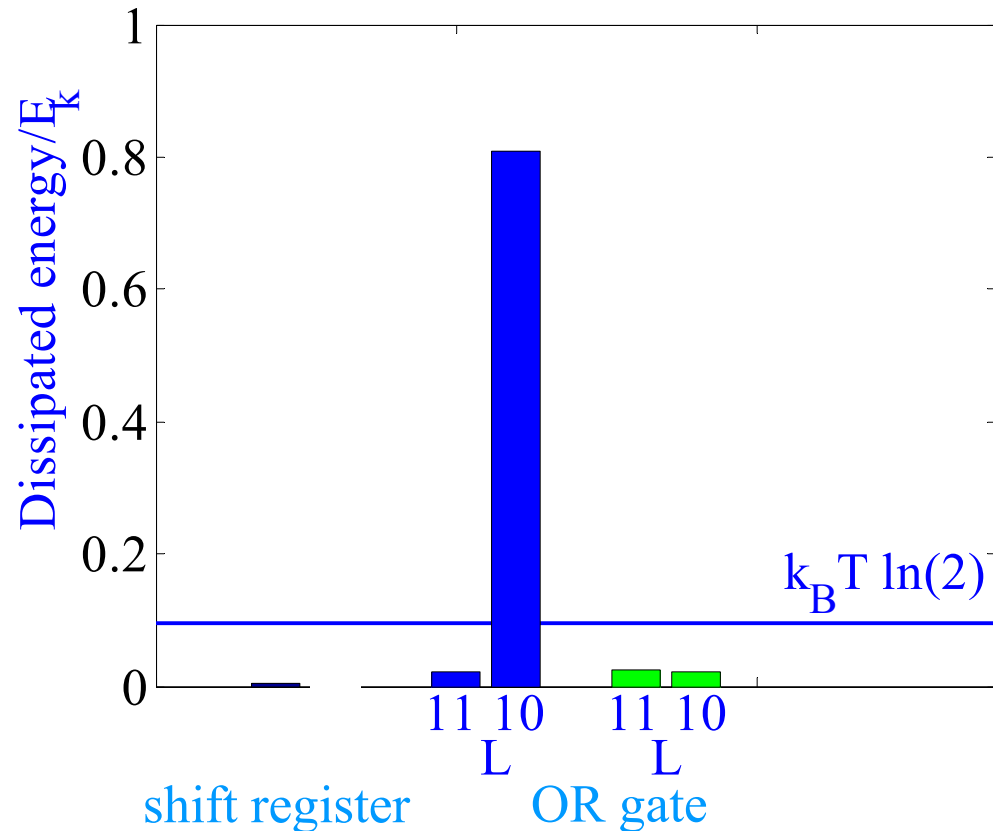
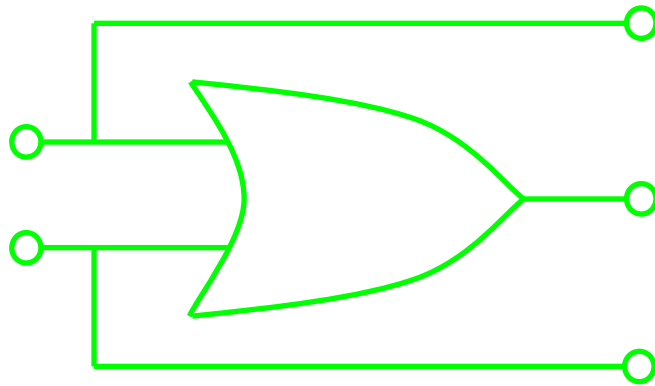


Notre Dame
Center for Nano Science
and Technology





Energy dissipation in the OR gate



Energy dissipation greatly reduced with inputs echoed to outputs

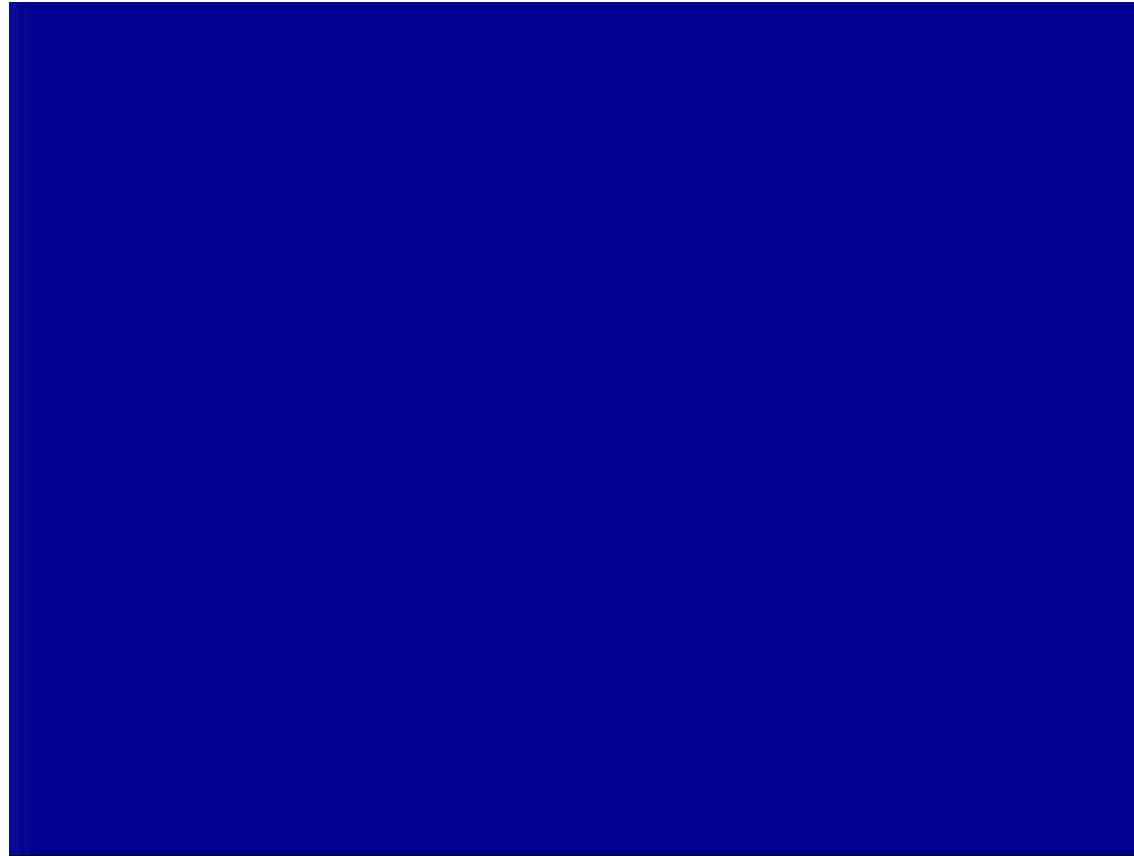


Notre Dame
Center for Nano Science
and Technology





Bennett clocking of QCA



Output is used to erase intermediate results.

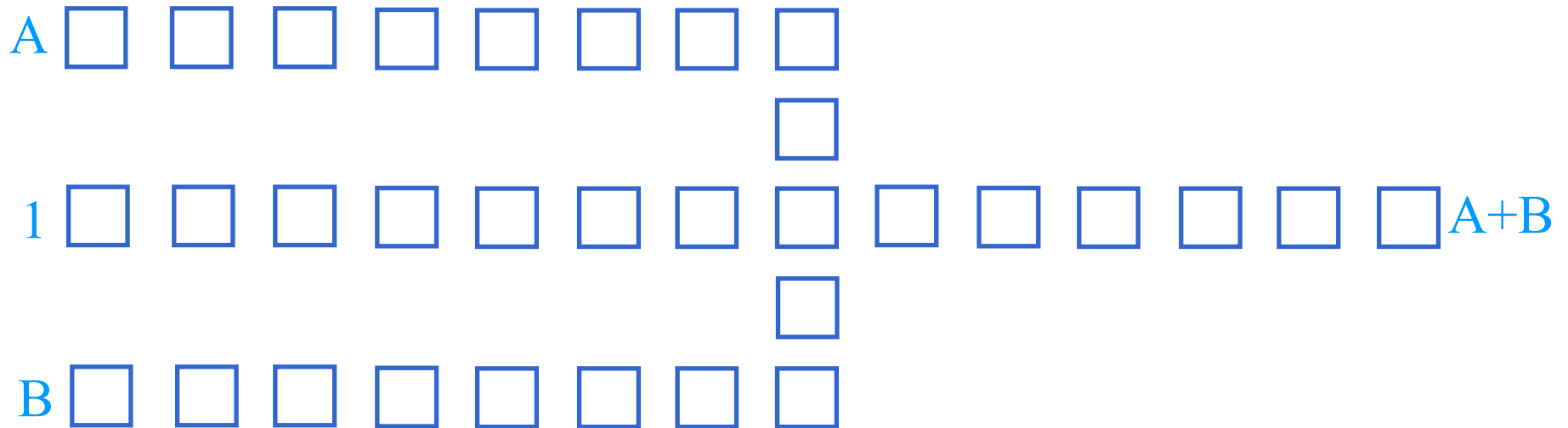
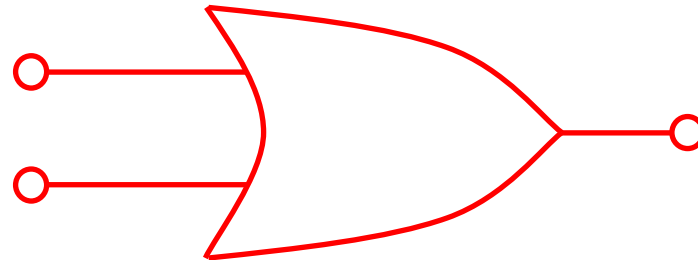


Notre Dame
Center for Nano Science
and Technology





Test circuit: OR gate



Bennett clocked OR gate

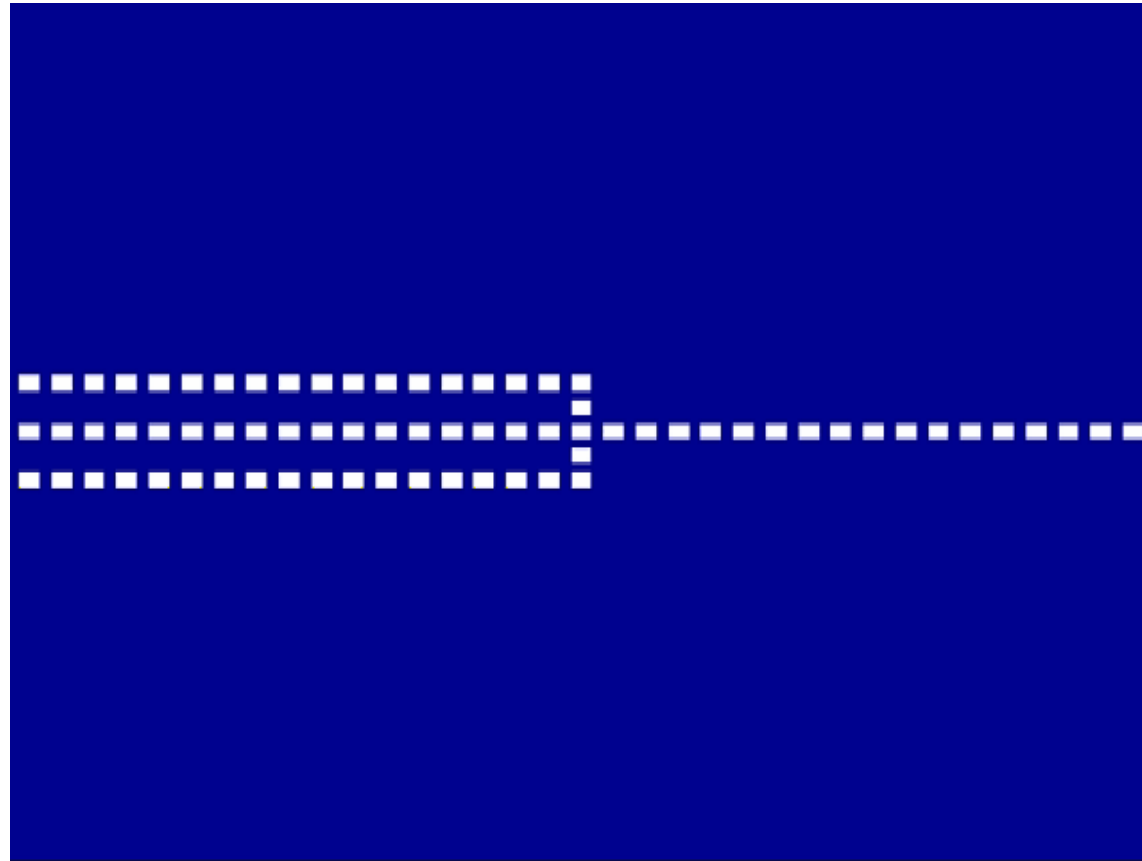


Notre Dame
Center for Nano Science
and Technology





Bennett clocking of QCA



For QCA no change in layout is required.

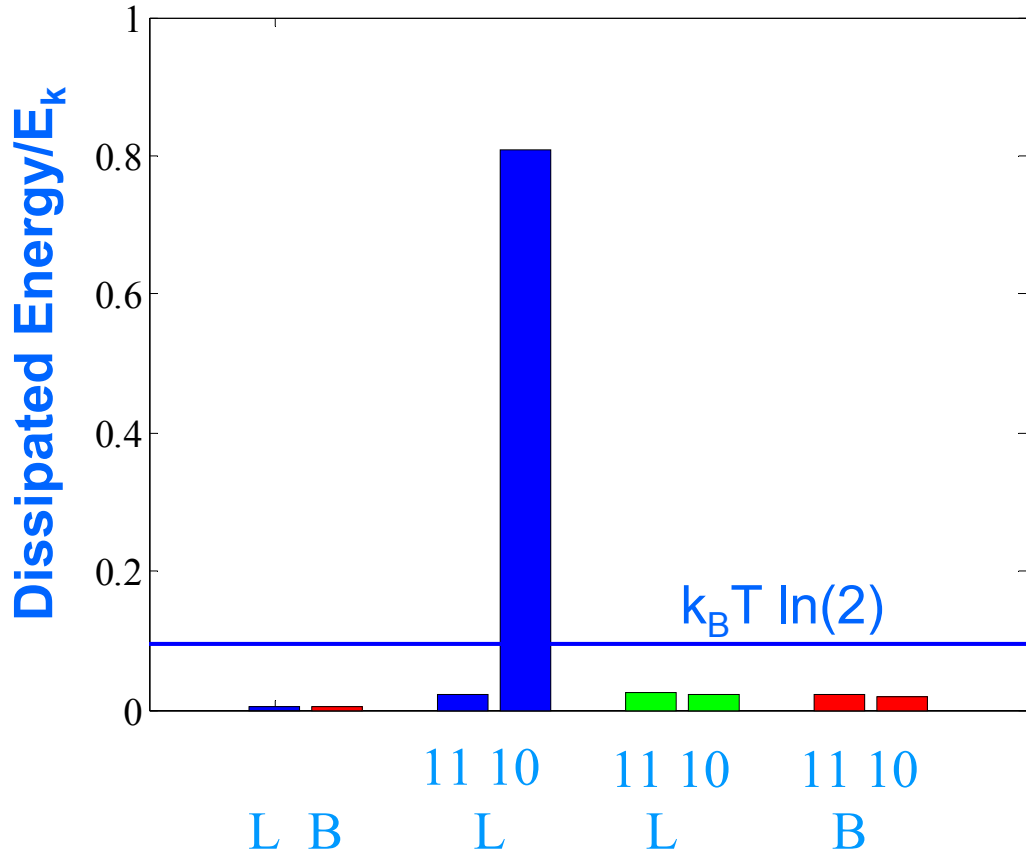
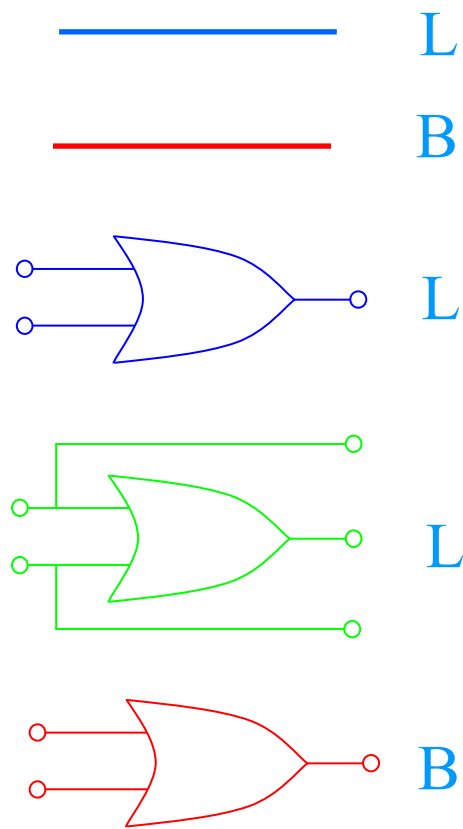


Notre Dame
Center for Nano Science
and Technology





Bennett-style computation may be practical in QCA



Direct time-dependent calculations shows: Logically reversible circuit can dissipate much less than $k_B T \ln(2)$





QCA implementations

- Semiconductor-dot QCA
 - SiGe quantum fortresses
 - Silicon P-doping
 - GaAs
 - Silicon dot SET's
- Magnetic QCA
- Metal-dot QCA
- Molecular QCA
- CMOS analogue

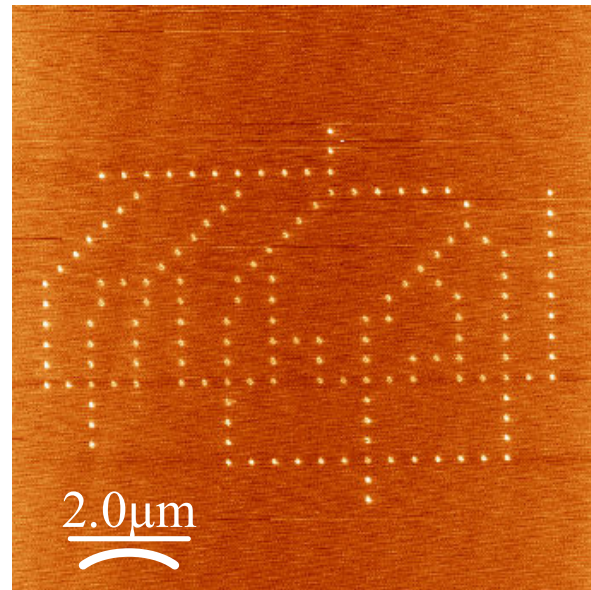
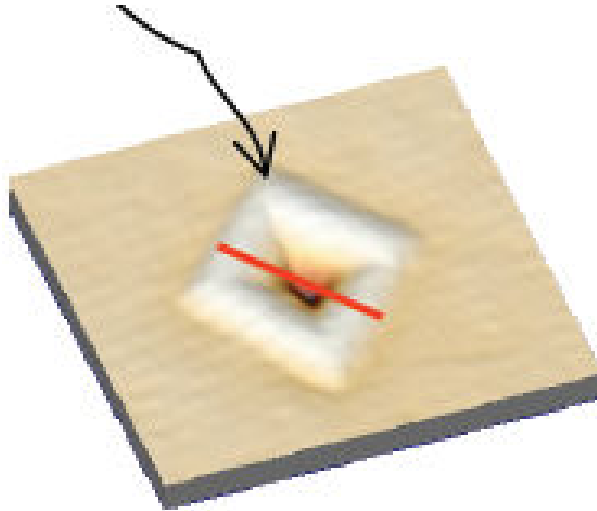


LDRD Status

- Current work underway at Sandia to find novel ways to create QCA cells
- SiGe identified as potential material system
- MBE growth of SiGe Quantum Fortresses underway
- FIB pattern designed and fabricated to allow electrical testing of Quantum Fortresses
- Electrical contact and testing will be undertaken this fall at University of Notre Dame



SiGe Quantum Fortresses



- Potential new way to create QCA cells
- Self-Assembled with 4 fold symmetry
- Fortress growth can be directed



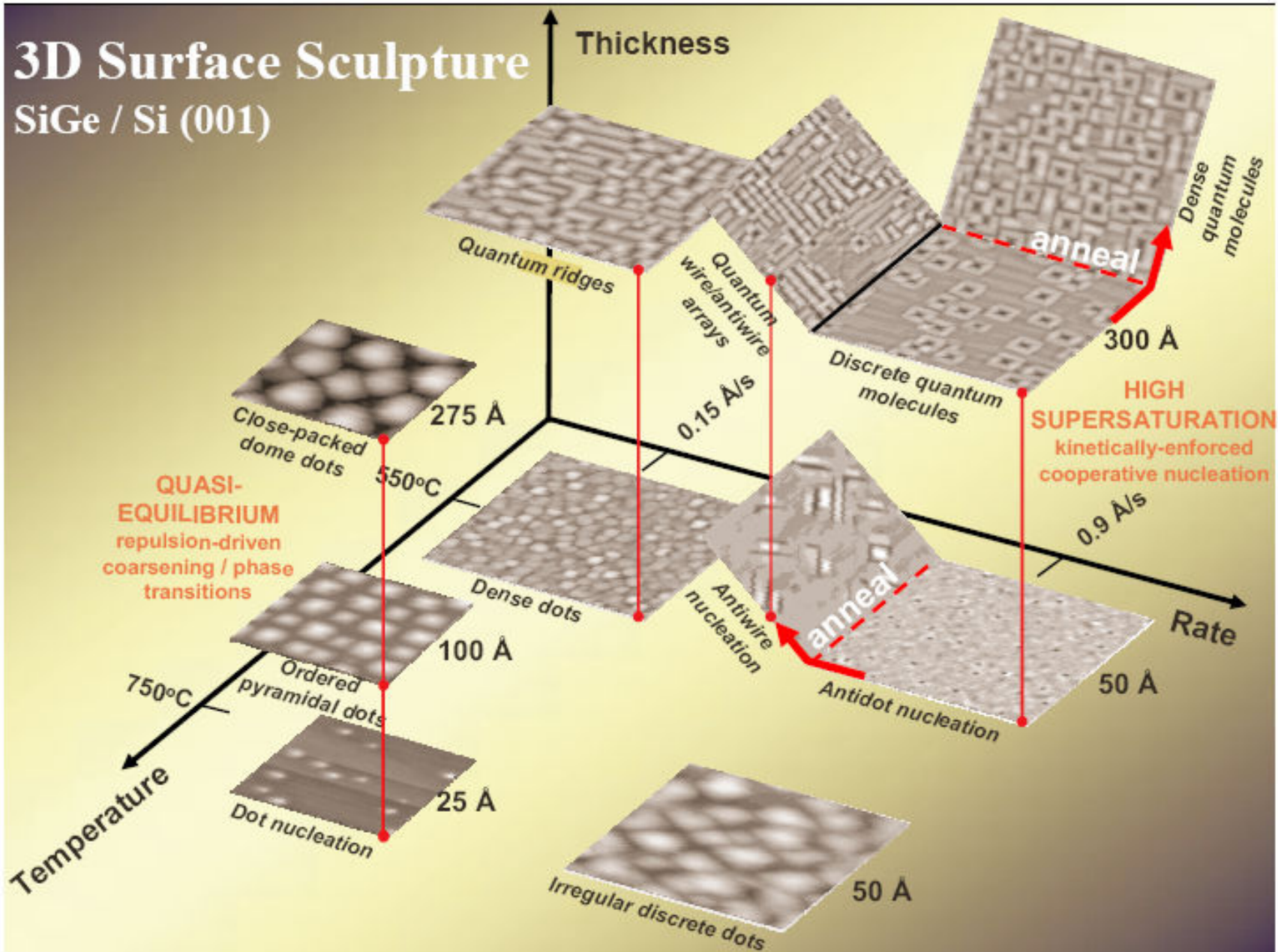
SiGe Quantum Fortresses

- When grown at optimum conditions, Silicon Germanium alloys form “fortress-like” structure
- 4-fold symmetry of structure may allow it to be used as a QCA cell
- Growth can be directed by introducing defects to the crystal surface



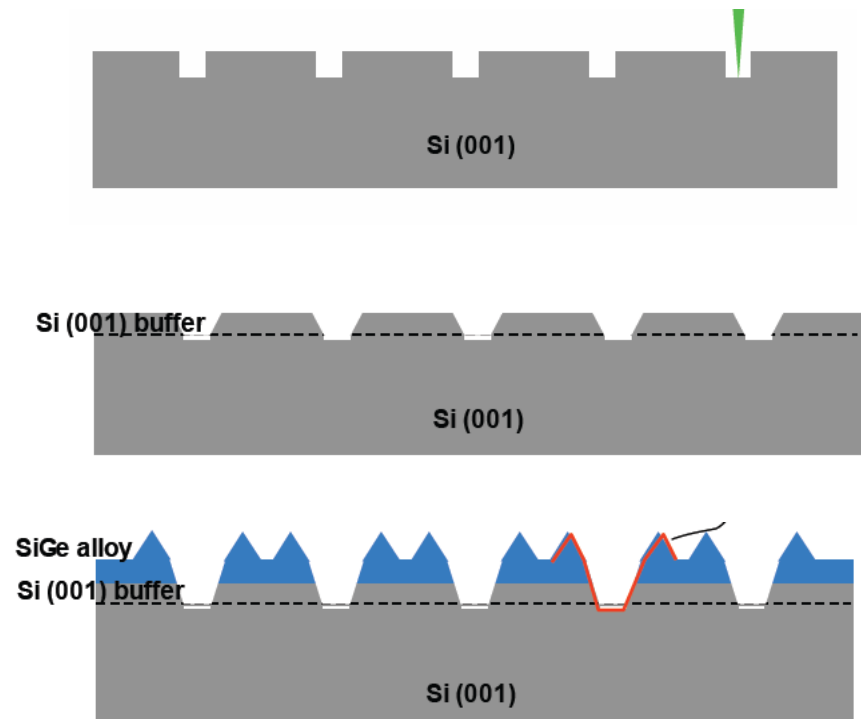
3D Surface Sculpture

SiGe / Si (001)

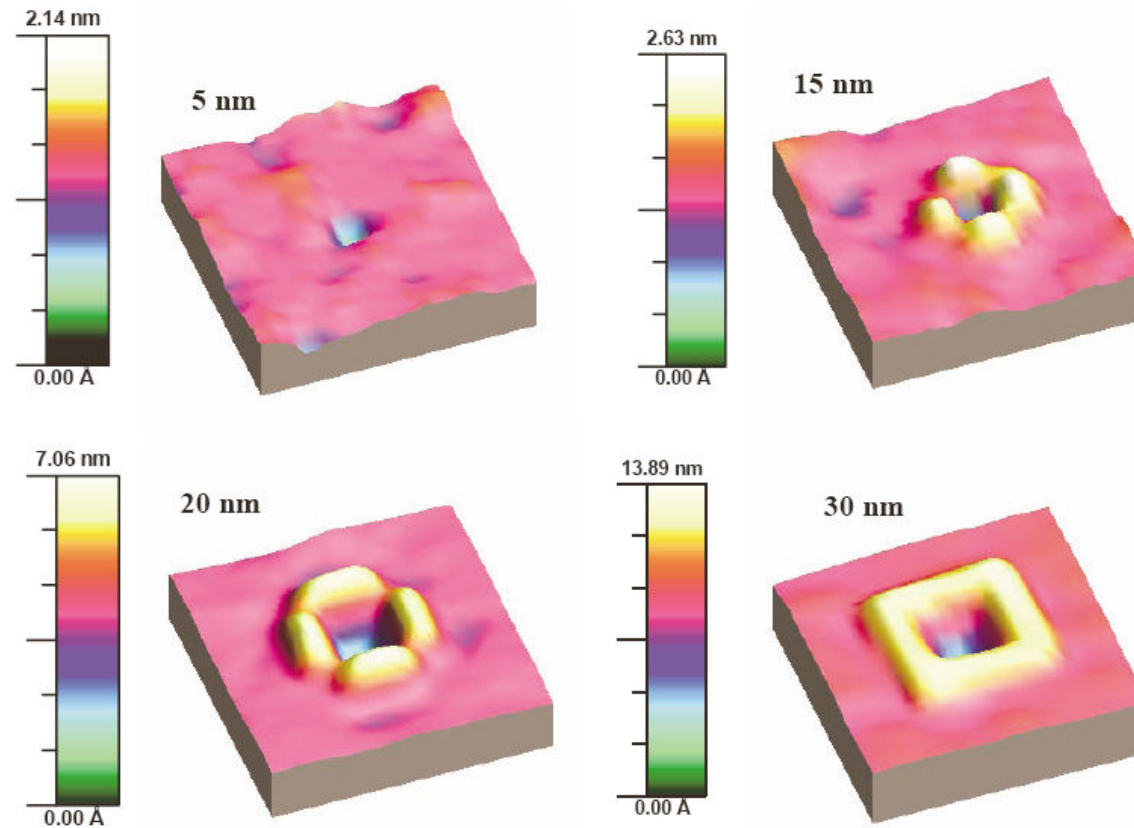


SiGe Quantum Fortresses

- Silicon is patterned using a gallium FIB
- 7nm Si buffer is grown
- $.6\text{\AA}/\text{s}$ Si and $.3\text{\AA}/\text{s}$ Ge are grown, to a total thickness of 200\AA .



Quantum Fortress Growth

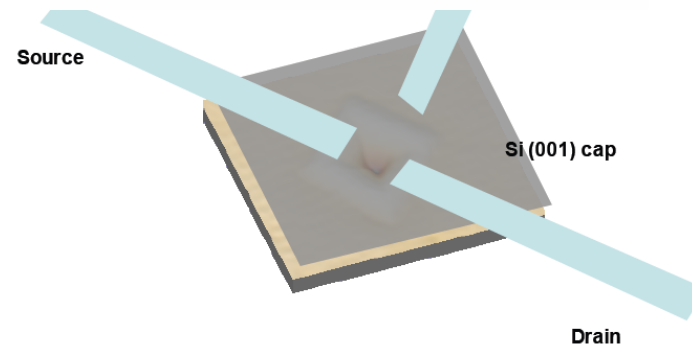
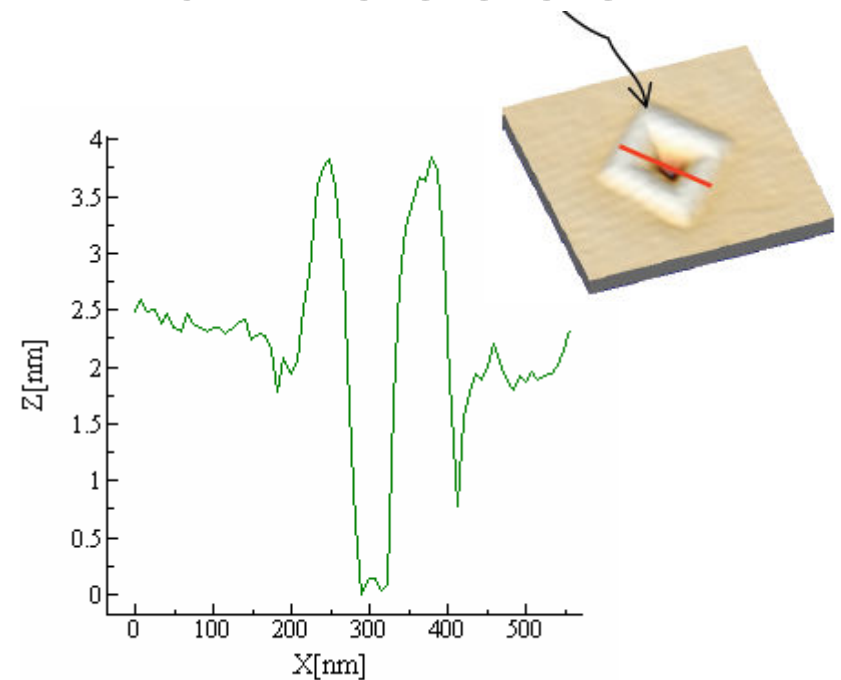


h nm Ge_{0.3}Si_{0.7}/Si(100), 550° C, 0.09 nm/s



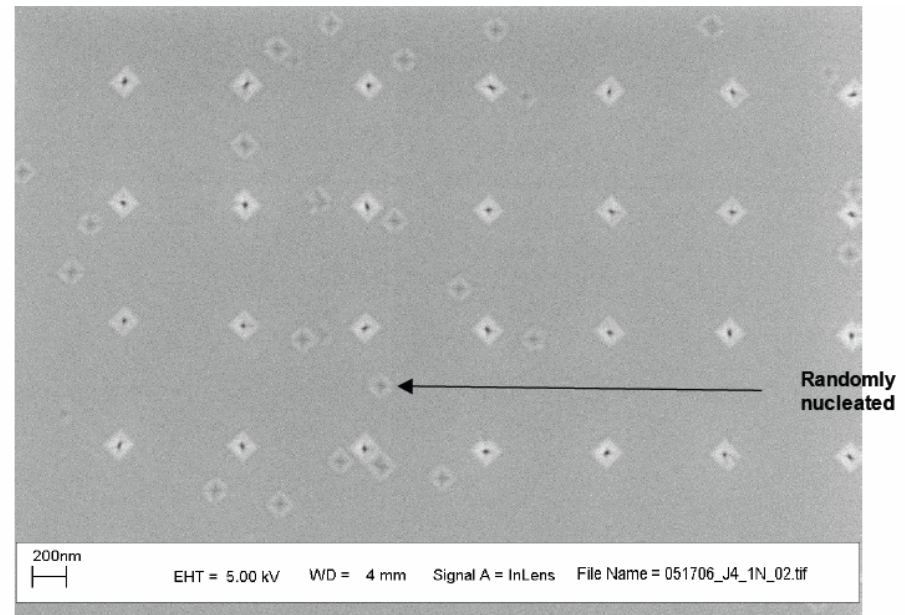
SiGe Quantum Fortresses

- Quantum fortresses form around the gallium damage sites, roughly 220nm x 220nm.
- X-Ray Diffraction indicates that significant germanium enrichment occurs, allowing carrier confinement
- These may be used as electrical devices such as SETs or Quantum Cellular Automata cells



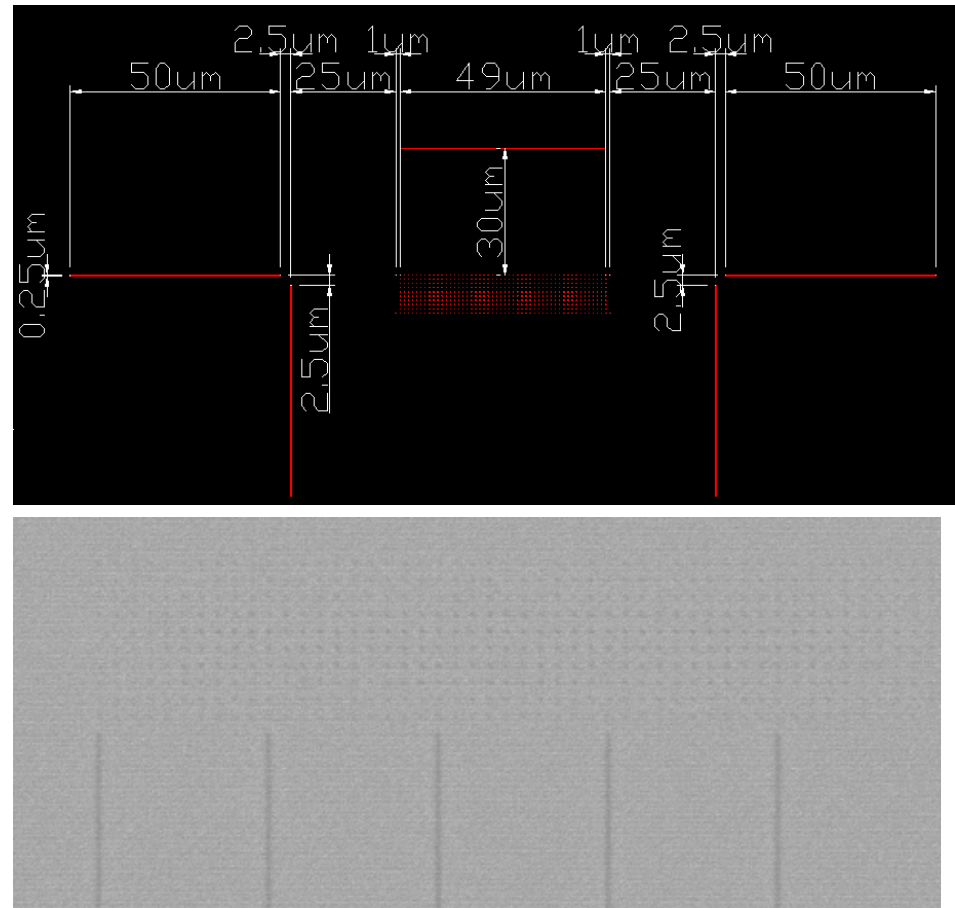
SiGe Quantum Fortresses

- Undirected nucleation also occurs, increasing the quantum dot density beyond the original pattern

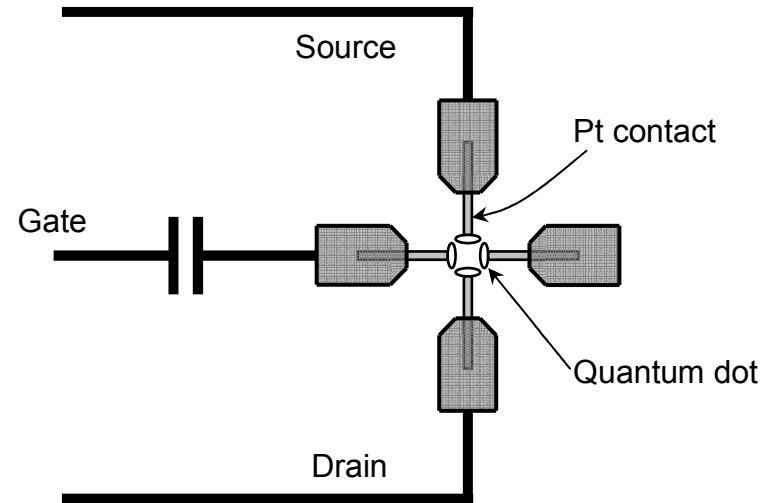
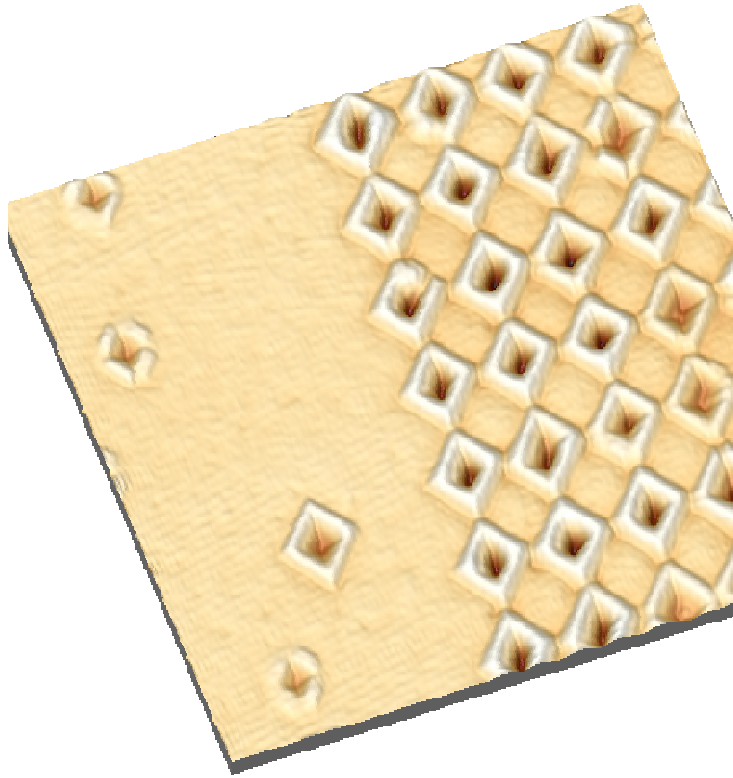


Quantum Fortress Patterning

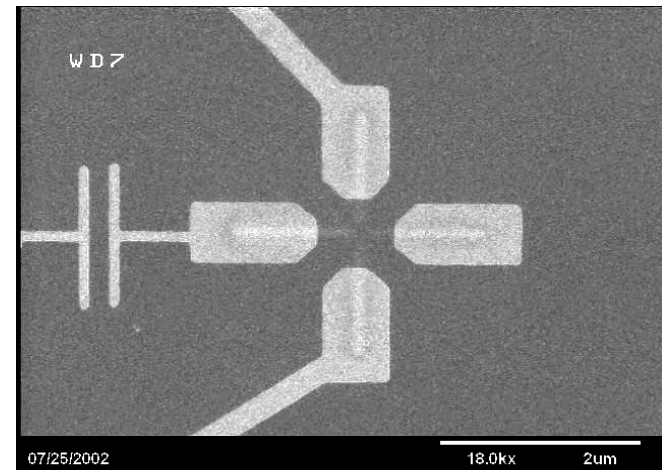
- Current experiments are attempting to grow capped, aligned samples which can be contacted using e-beam lithography and metal deposition
- Grid of Dots with fiducial marks created to facilitate electrical testing



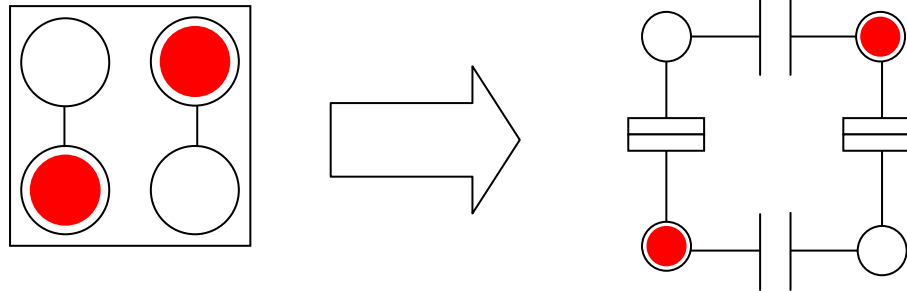
Quantum Fortress QCA



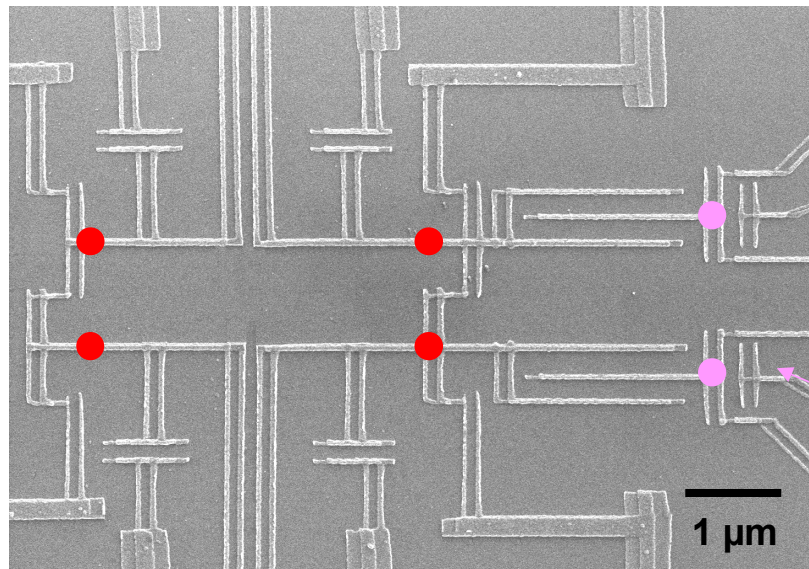
FIB are used to deposit Pt contacts to ease the alignment requirements of the E-beam lithography.



Metal-dot QCA implementation



Metal tunnel junctions



Al/AlO₂ on
SiO₂

electrometers

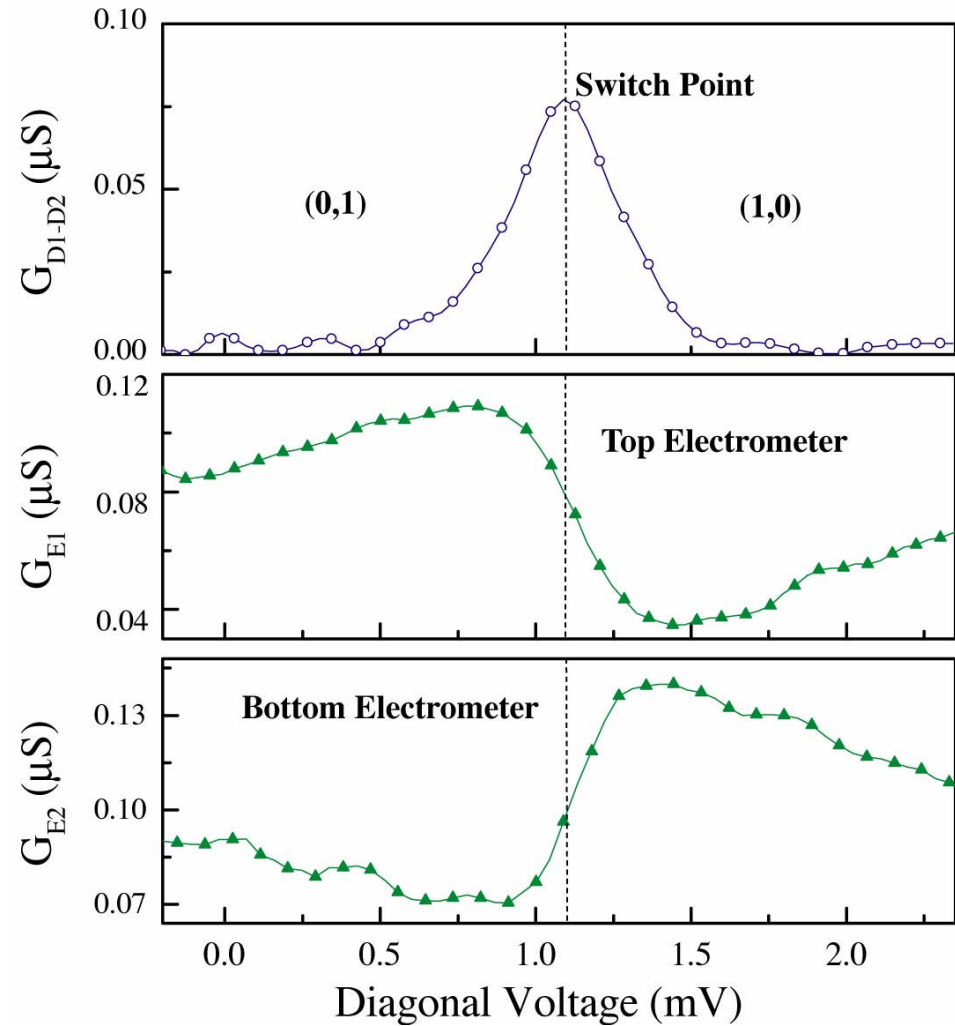
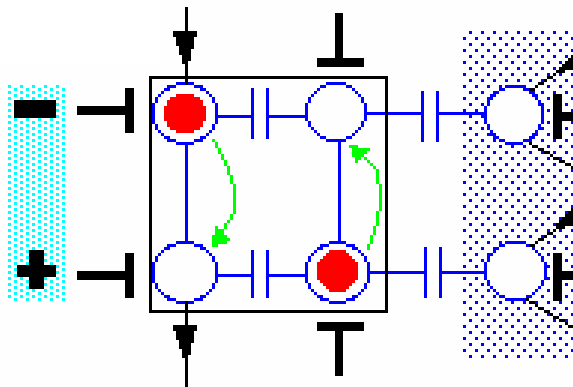
70 mK

“dot” = metal island



Metal-dot QCA cells and devices

- Demonstrated 4-dot cell

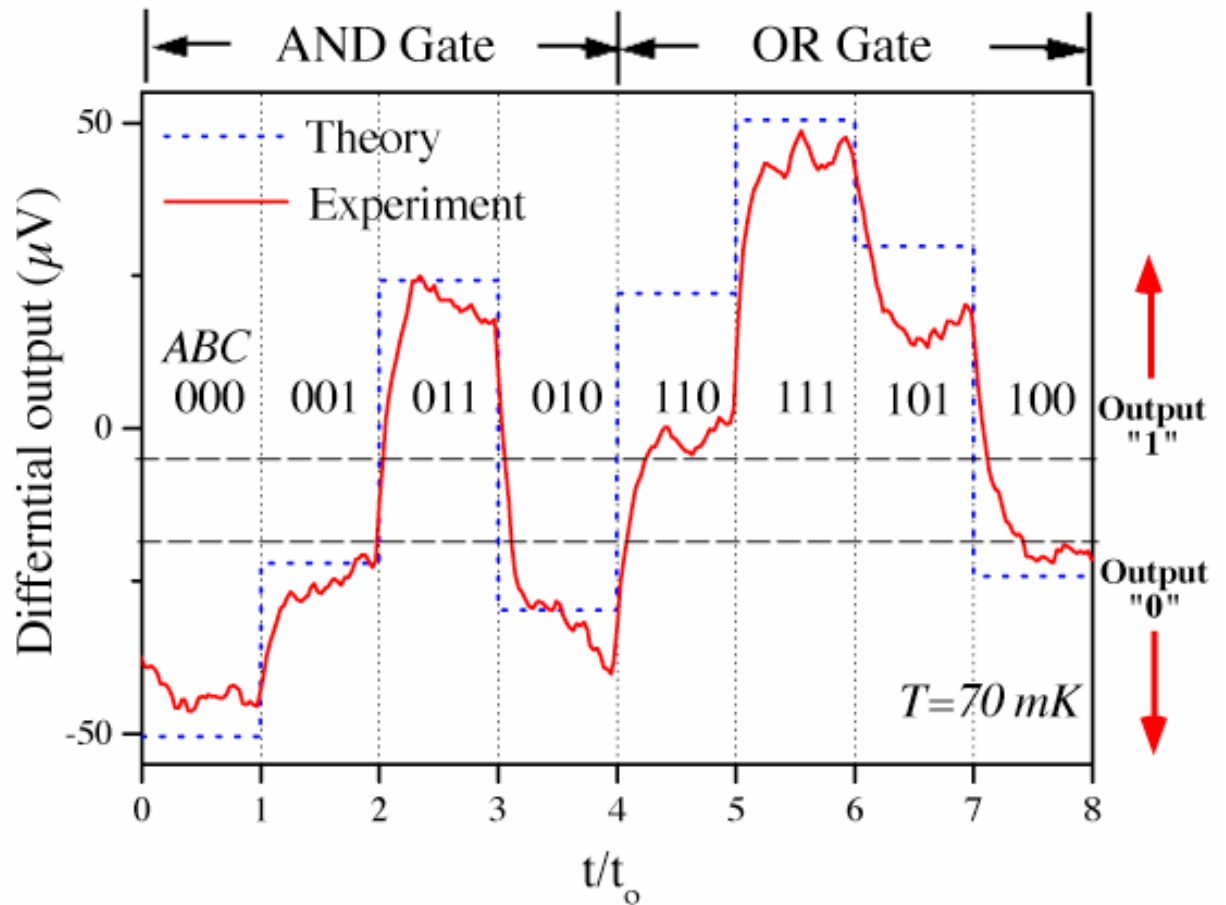
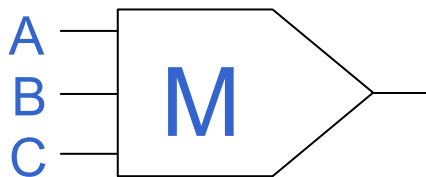
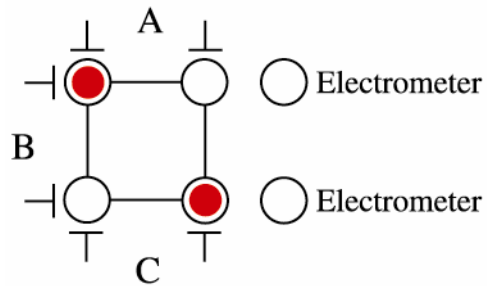


A.O. Orlov, I. Amlani, G.H. Bernstein, C.S. Lent, and G.L. Snider, *Science*, **277**, pp. 928-930, (1997).



Majority Gate

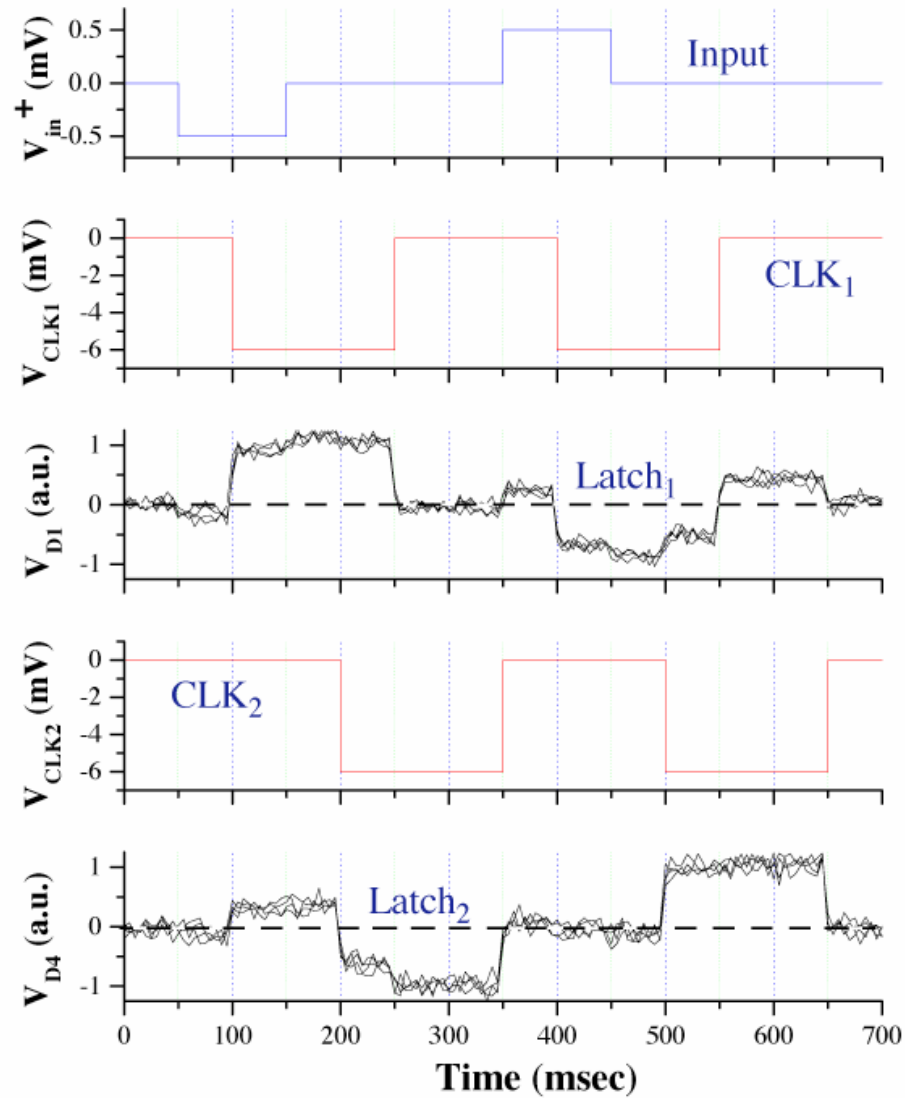
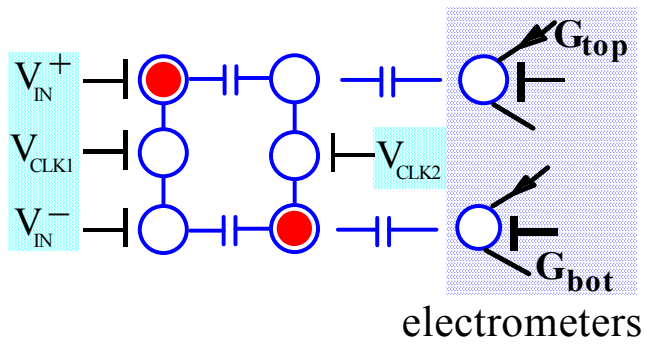
	A	B	C	Output
AND gate	0	0	0	0
	0	0	1	0
	0	1	1	1
	0	1	0	0
OR gate	1	1	0	1
	1	1	1	1
	1	0	1	1
	1	0	0	0



Amlani, A. Orlov, G. Toth, G. H. Bernstein, C. S. Lent, G. L. Snider, *Science* **284**, pp. 289-291 (1999).

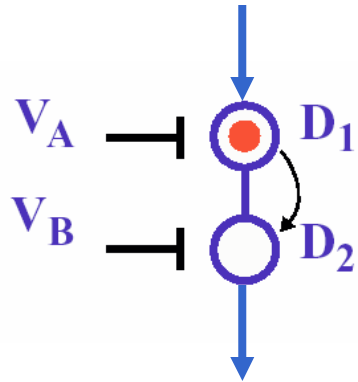


QCA Shift Register

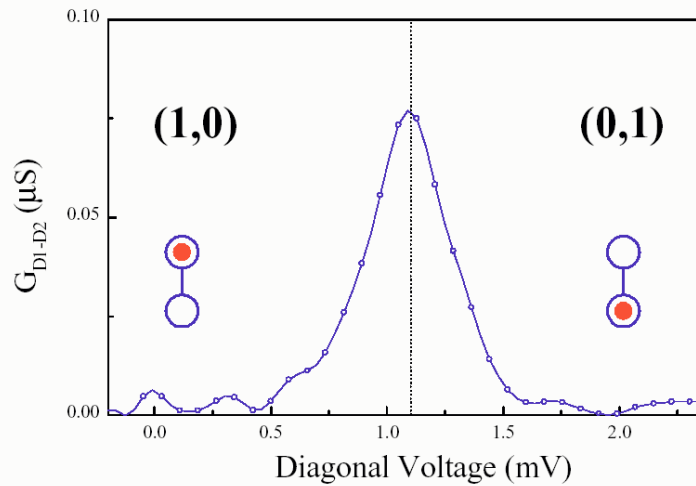


Electron Switching in QCA

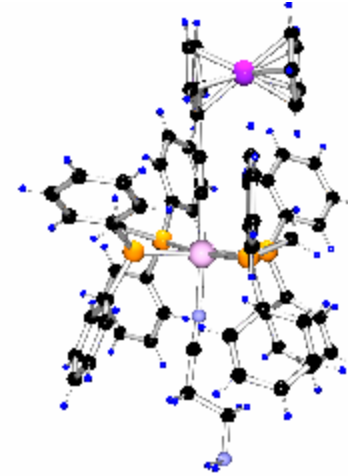
Metal Dots



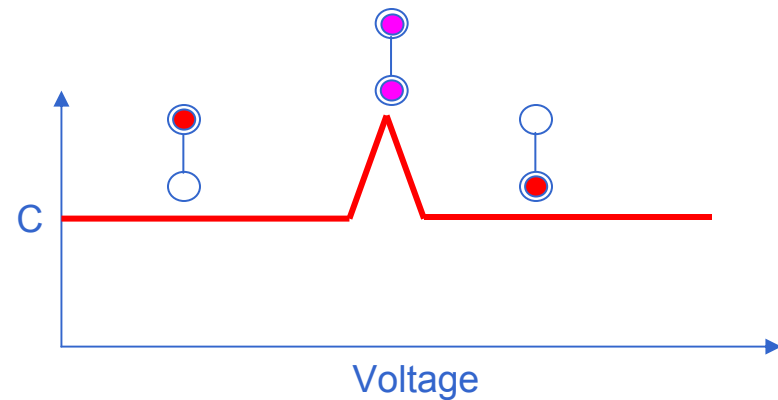
Measure conductance



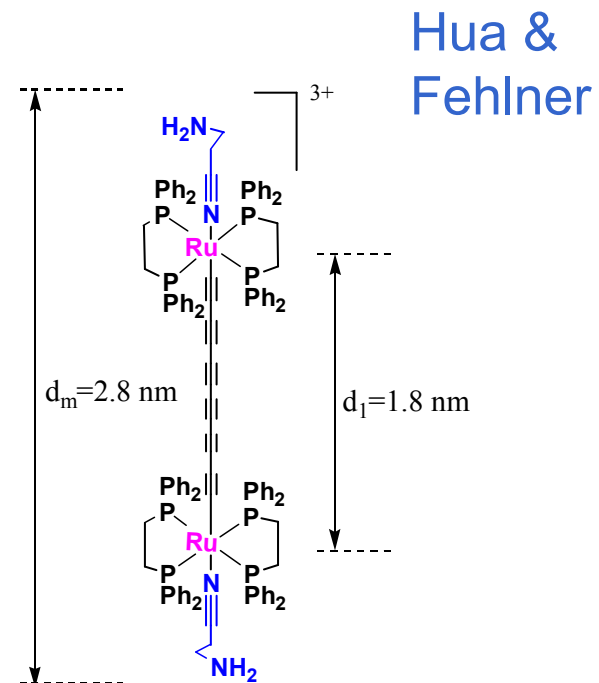
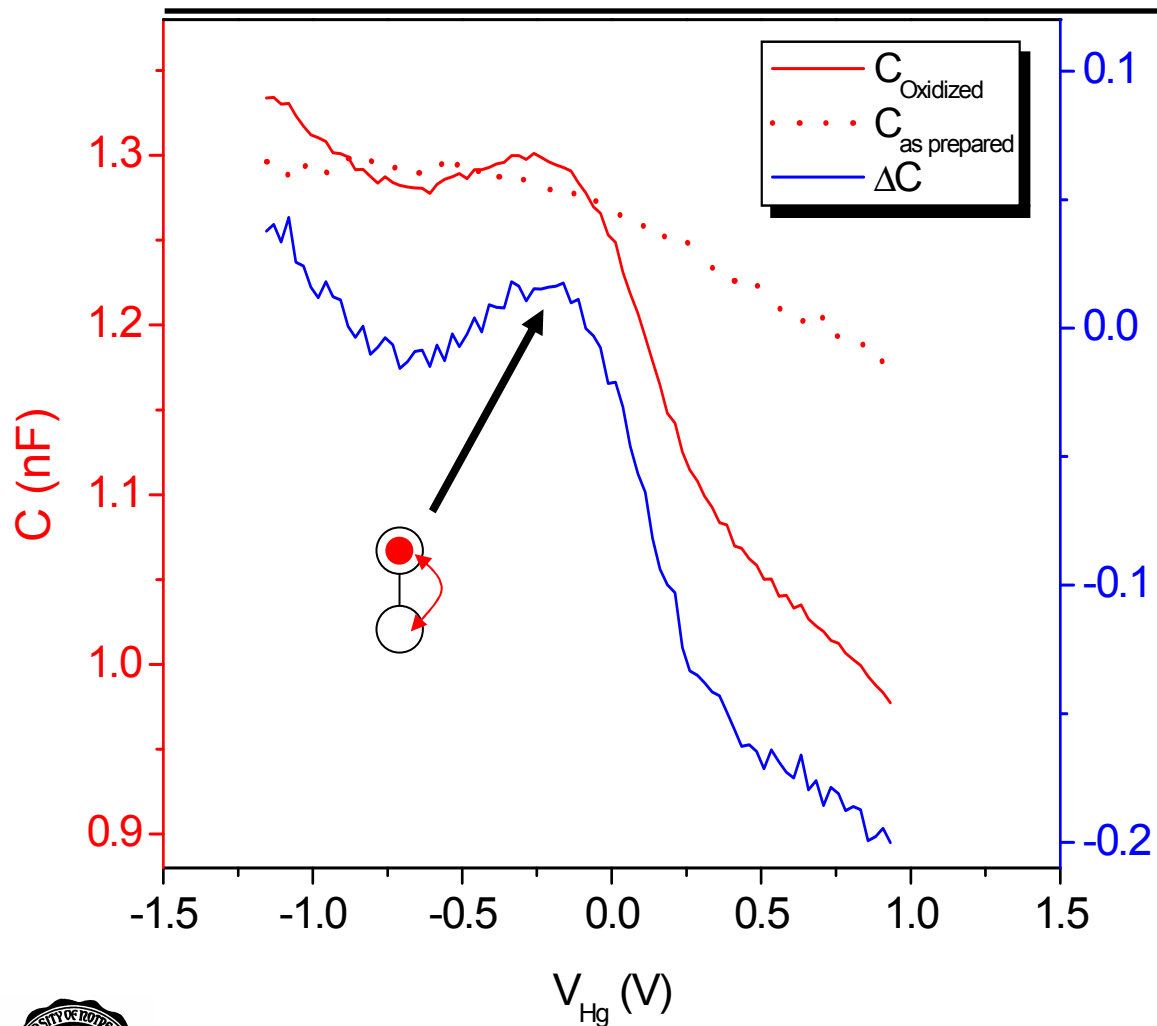
Molecular Dots



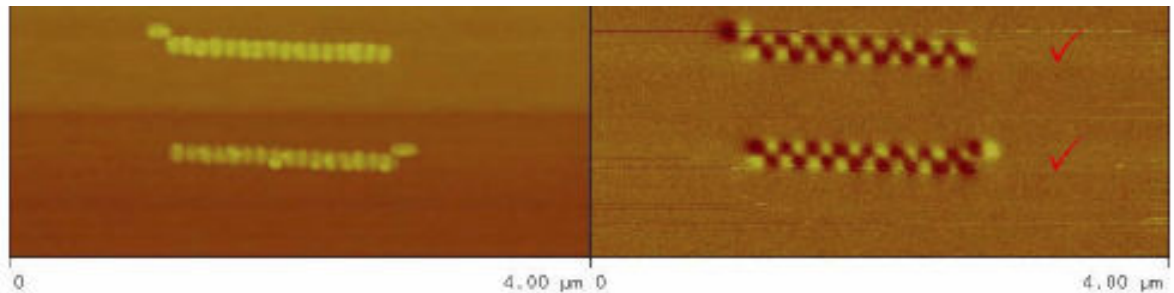
Measure capacitance



Double-dot click-clack

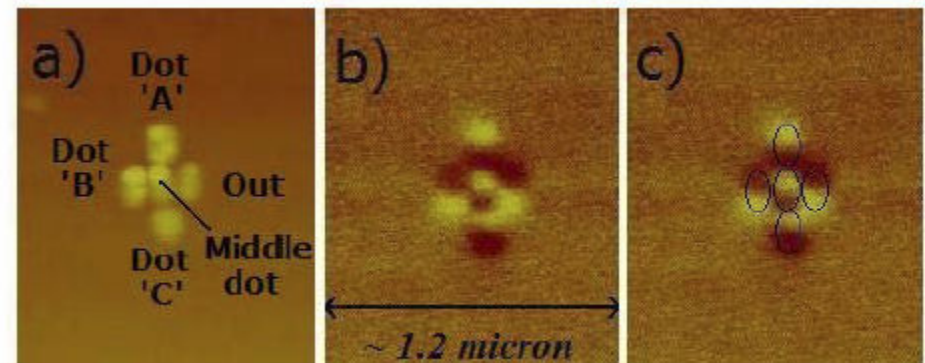


Magnetic QCA cell



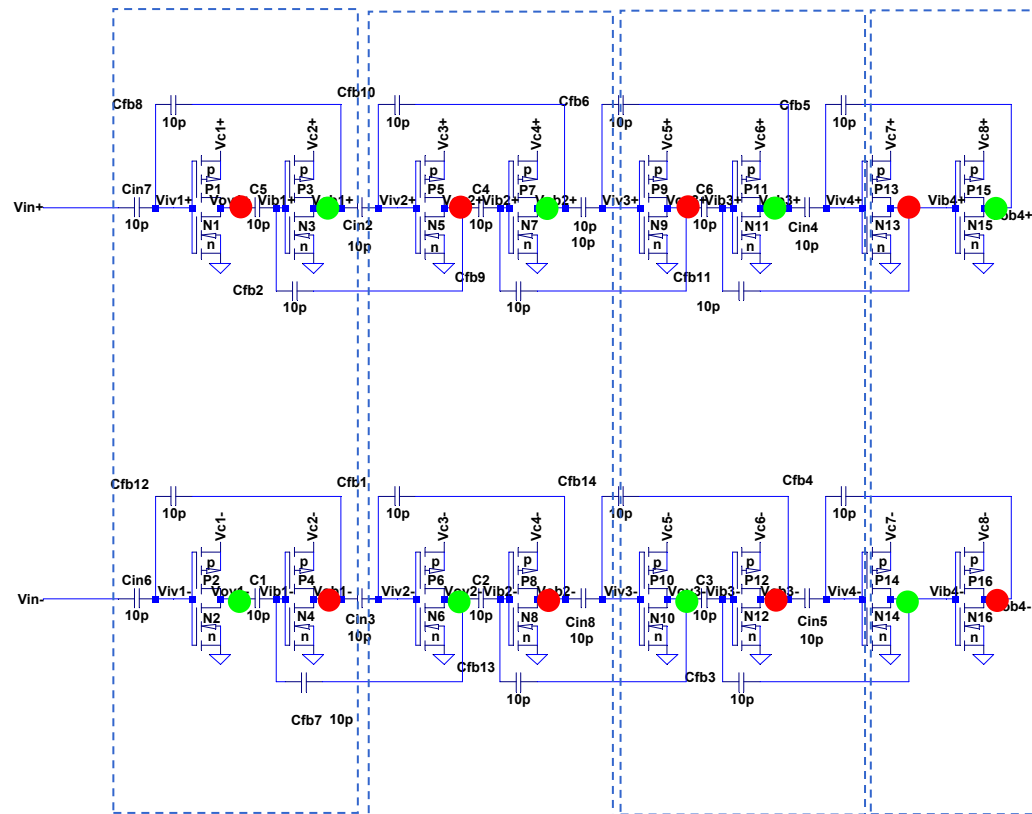
Bernstein, Imrae, Metlushko, Orlova, Zhou, Csaba, Porod, Magnetic QCA Systems, *Microelectronics Journal*, 36, 619 (2005).

- Dots are permalloy islands
- Limited to $> \sim 20$ nm sizes



CMOS analogue of QCA

- “Dots” are CMOS nodes
- Instead of charge quantization use transistor action
- Room temperature
- Slow performance
- Test-bed for architecture and power dissipation ideals



Silicon P-dot QCA cell

APPLIED PHYSICS LETTERS 89, 013503 (2006)

Demonstration of a silicon-based quantum cellular automata cell

M. Mitic,^{a)} M. C. Cassidy, K. D. Petersson,^{b)} R. P. Starrett, E. Gauja, R. Brenner,
R. G. Clark, and A. S. Dzurak

Centre for Quantum Computer Technology, School of Electrical Engineering and School of Physics, The University of New South Wales, Sydney, New South Wales 2052, Australia

C. Yang and D. N. Jamieson

Centre for Quantum Computer Technology, School of Physics, University of Melbourne, Victoria 3010, Australia

(Received 8 March 2006; accepted 18 May 2006; published online 5 July 2006)

We report on the demonstration of a silicon-based quantum cellular automata (QCA) unit cell incorporating two pairs of metallicly doped (n^+) phosphorus-implanted nanoscale dots, separated from source and drain reservoirs by nominally undoped tunnel barriers. Metallic cell control gates, together with Al-AIO_x single electron transistors for noninvasive cell-state readout, are located on the device surface and capacitively coupled to the buried QCA cell. Operation at subkelvin temperatures was demonstrated by switching of a single electron between output dots, induced by a driven single electron transfer in the input dots. The stability limits of the QCA cell operation were also determined. © 2006 American Institute of Physics. [DOI: 10.1063/1.2219128]

- Dots defined by implanted phosphorus
- Single-donor creation foreseen
- Direct measurement of cell switching

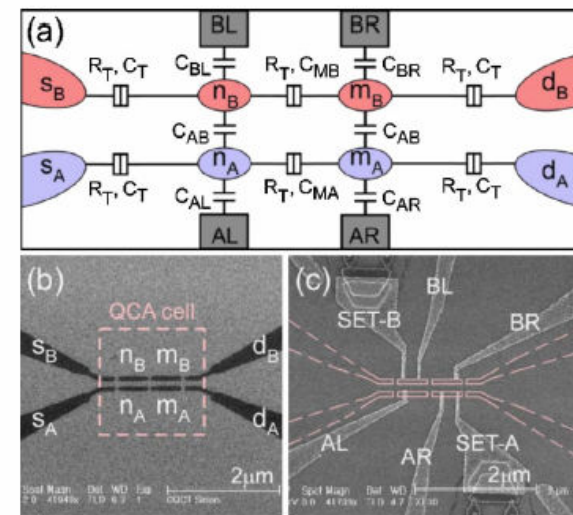
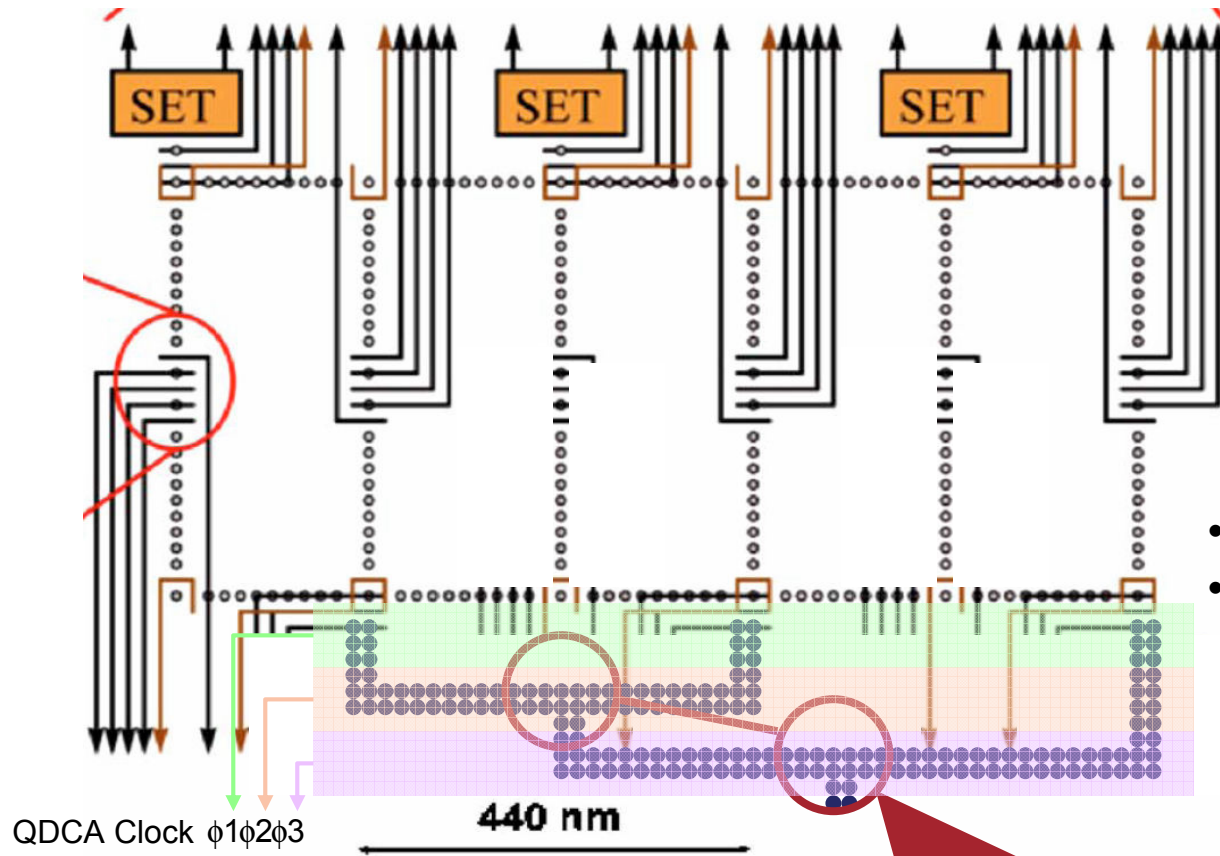


FIG. 1. (Color online) (a) Simplified circuit equivalent of the QCA cell, (b) SEM image of phosphorus-implanted n^+ regions (dark in image), and (c) SEM image of completed device. The buried n^+ dots and leads are marked using dashed lines.



QDCA Logic Directly Attached to QC



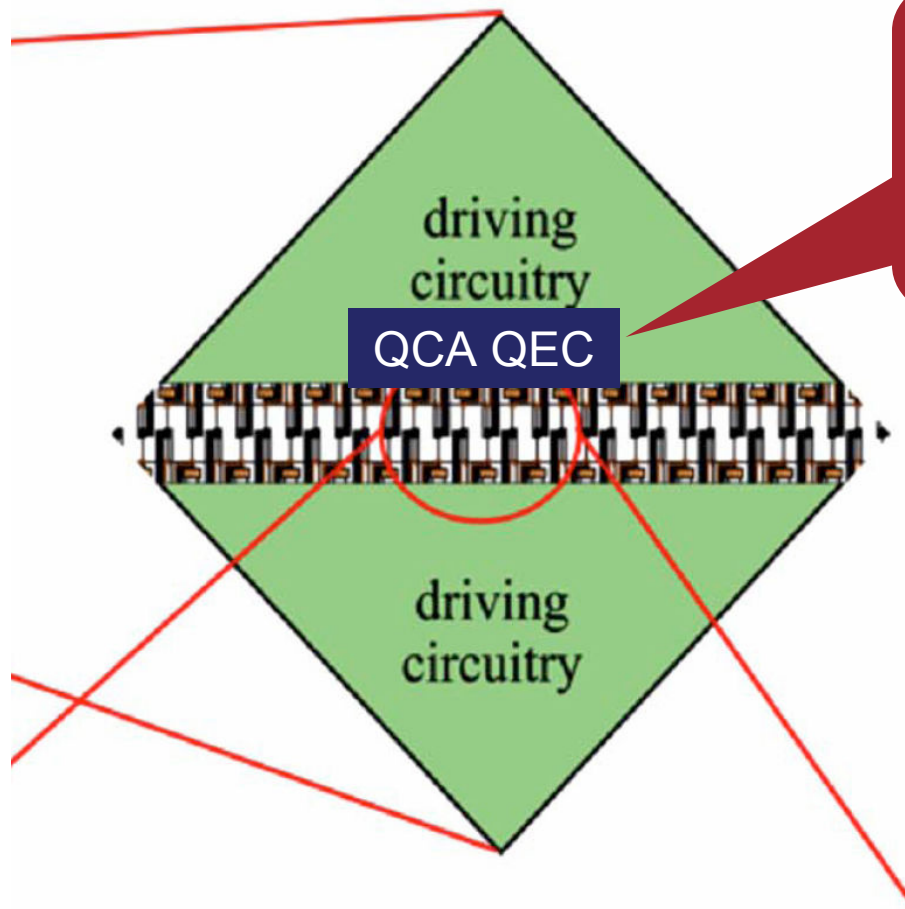
Advantages:

- Integration on one substrate
- Low power dissipation reduces load on cooling system

Classical QCA Gate
(to scale)



Self-Contained Classical+Quantum Logic

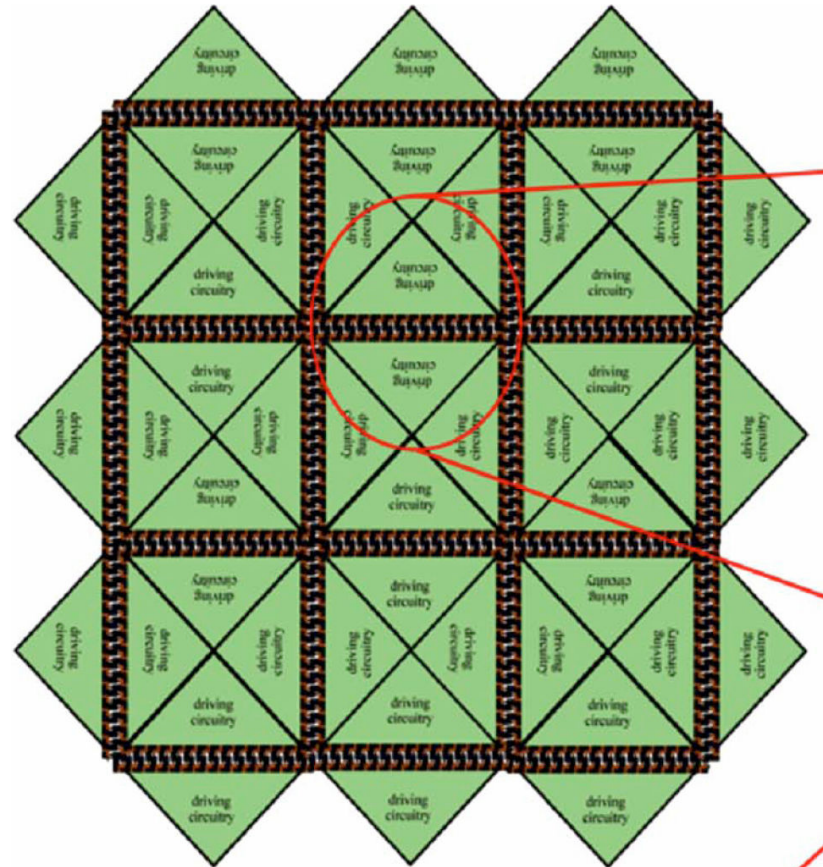


Steane 5-bit QEC
Measure-Classical
Syndrome-Correct
with no external
connection except
clock

Base diagram from Physical Review B 74, 045311 2006,
Two-dimensional architectures for donor-based quantum computing



Large QC and QCA Arrays



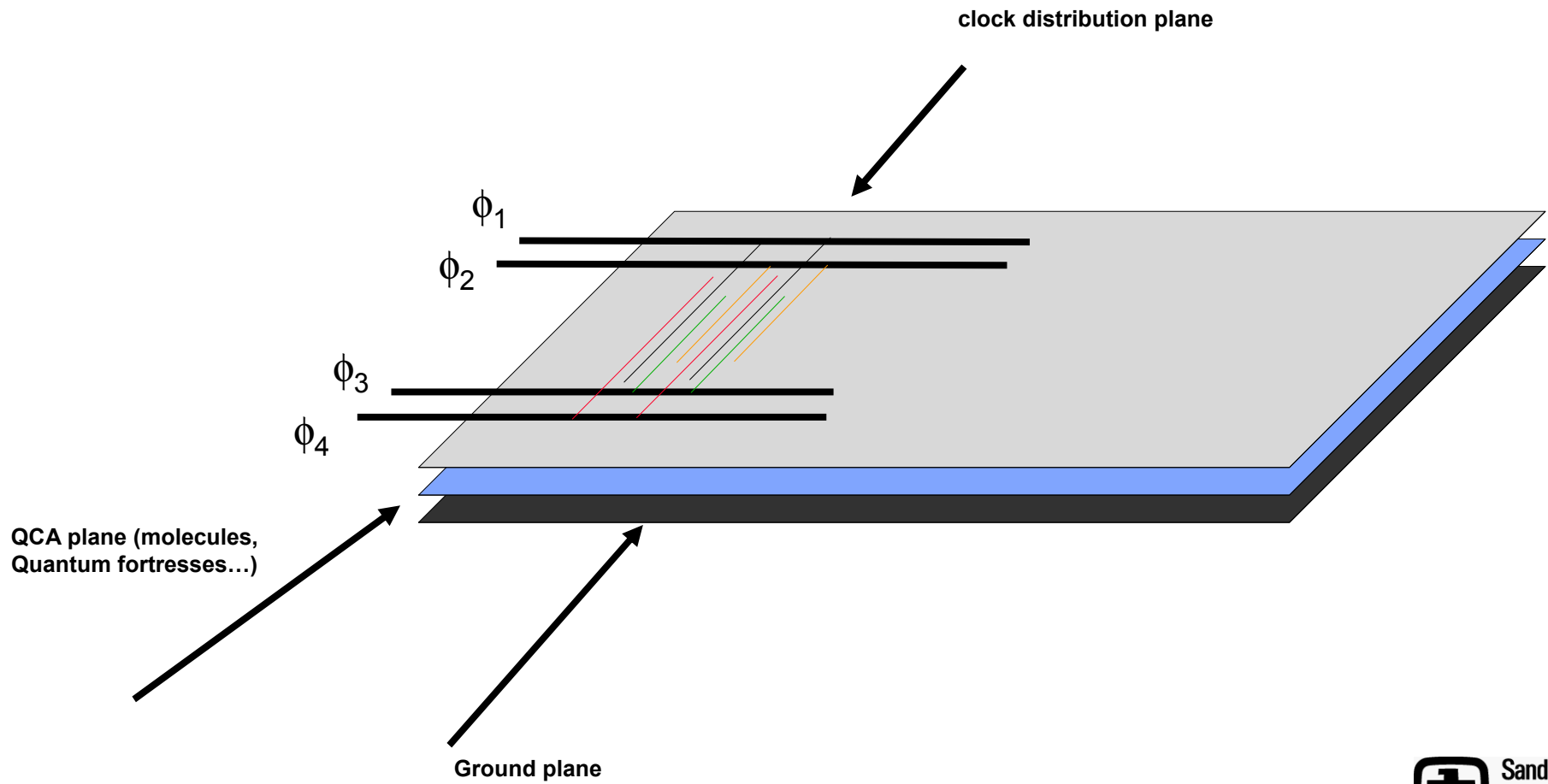


Advantages

- QCA logic “lives” in the single electron world, thus avoiding the need to amplify single electron signals to CMOS levels
- QCA logic would be used to execute the classical part of QEC recovery mechanisms, which is most (e. g. 99%) of the activity in a projected QC
- Each QCA “island” would consume less resources than SET, amplifier, bonding pad, and cable to controller through cryostat it replaces
- QCA would allow the classical circuitry to be implemented on-chip without over-heating the dilution refrigerator.

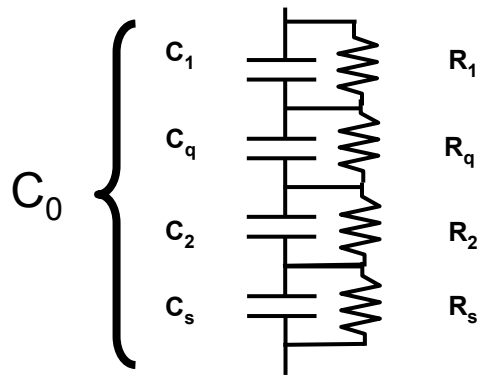
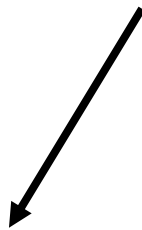
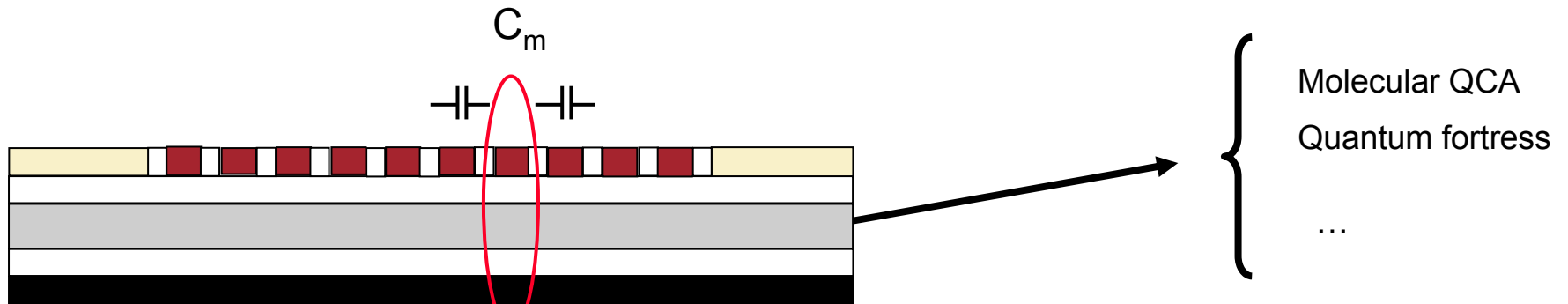


QCA chip isometric view





Implementations



Four layers:

1. Upper insulating;
2. QCA
3. Lower insulating
4. Substrate

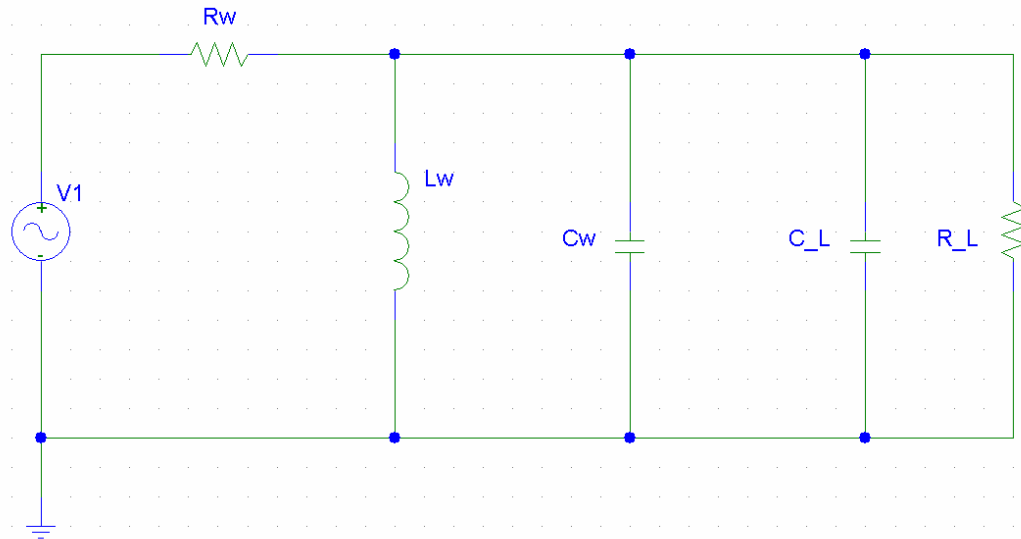
$$C = \epsilon_0 \epsilon_r A / d$$

$$R = \rho d / A$$

$$C_{\text{tot}} = C_L + kC_m$$



Clock with RLC resonant circuit



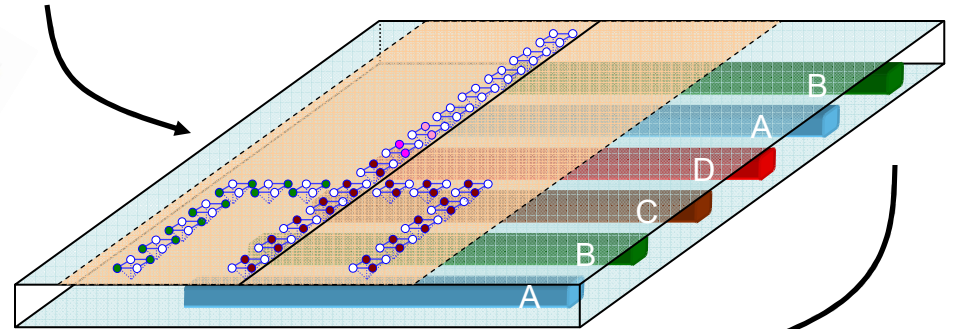
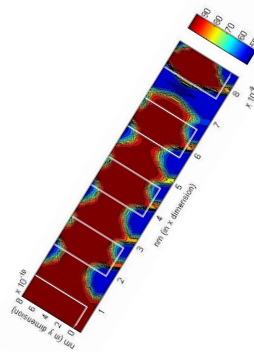
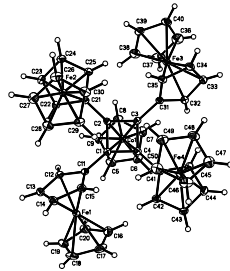
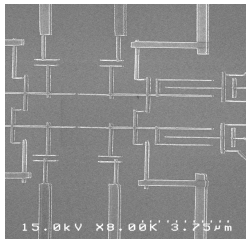
- Parallel RLC circuit
- Ideally at resonating frequency no current is drained from the voltage supply
- The dissipation is related to the parasitic resistance in through the layers of the clocked circuit and the resistance of the clock wires
- To achieve a resonating frequency of 1 THz the LC product should be $\sim 10^{-24}$
- Consequently $L \sim \text{pH}$ and $C \sim \text{pF}$



System + Application Architectures

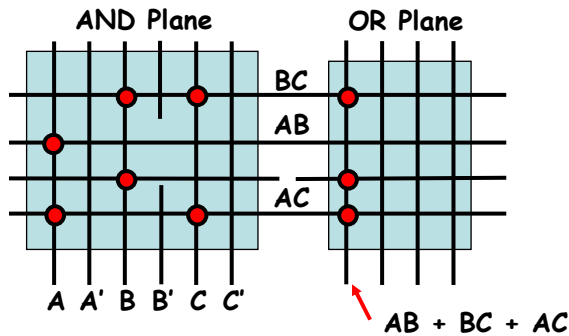
Grounded in device physics & simulation

Incorporate clock driven dataflow

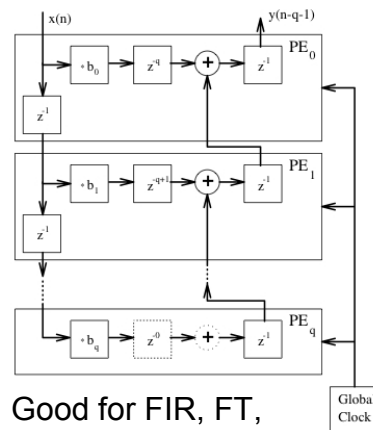


Device architecture maps well to many system architectures...

Reconfigurable

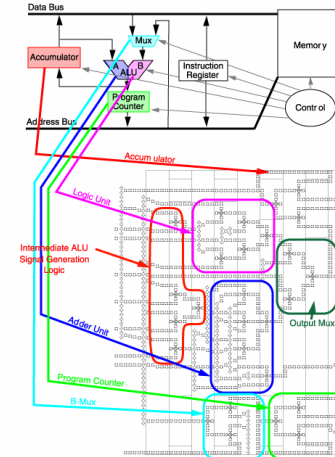


Systolic



Good for FIR, FT, Matrix multiply, graph algorithms, etc.

General Purpose



Notre Dame
Center for Nano Science
and Technology





Simulations

New devices
New circuits
New architectures



New simulators



Notre Dame
Center for Nano Science
and Technology





Simulation levels

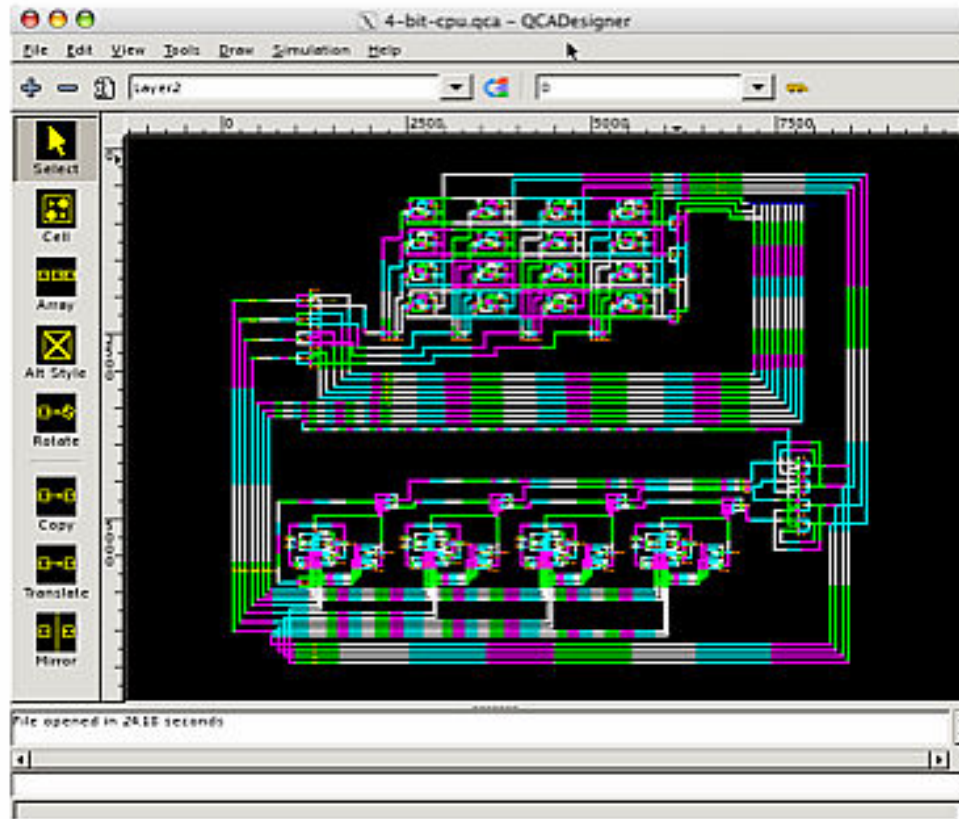
- 1) Quantum chemistry
Ab initio, all-electron, and approx.
- 2) Density matrix (coherence vector)
Quantum, dynamic, thermal effects, dissipation
- 3) Time-independent Schrod. Eq.
- 4) Semiclassical thermodynamic
- 5) Logic level
- 6) Architecture level

slow

fast



QCA design tools



QCADesigner

Konrad Walus

U. British Columbia

QCADesigner screenshot showing a simple 4-bit processor layout.



Notre Dame
Center for Nano Science
and Technology



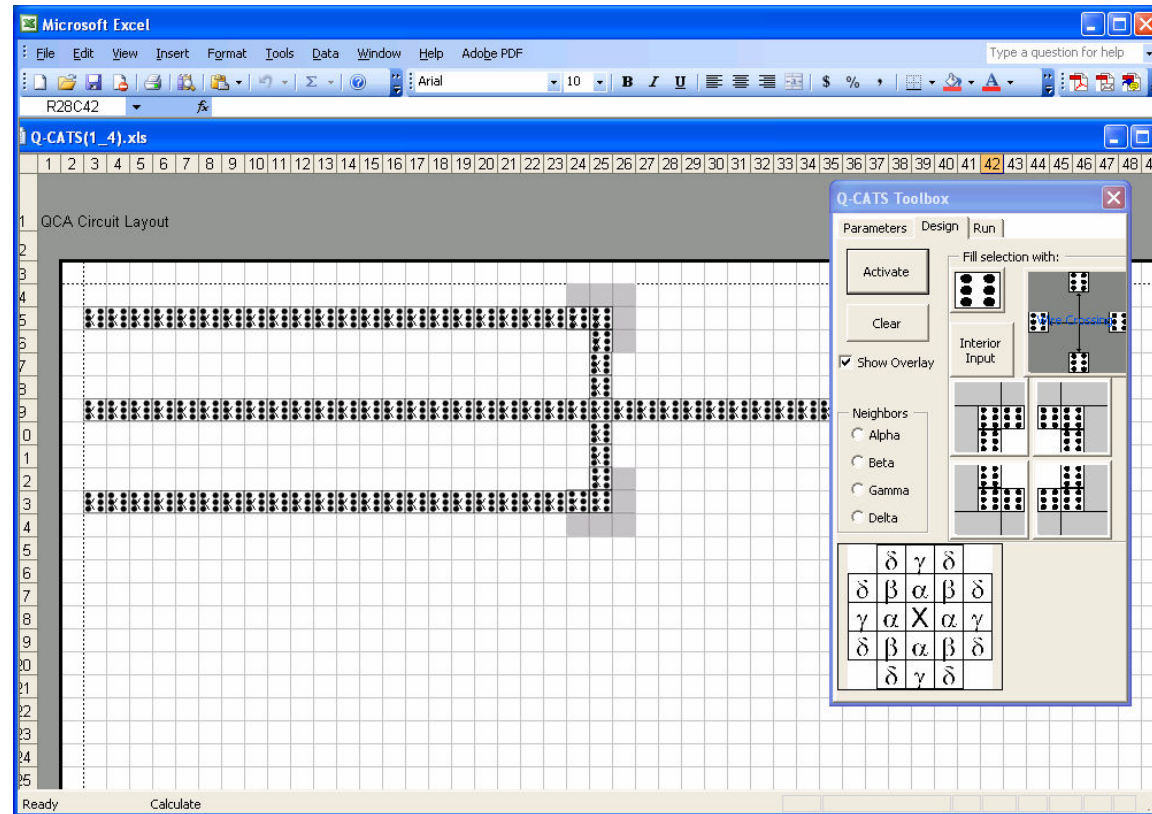


QCA design tools

QCATS

QCA
Thermodynamic
Simulator

Semiclassical



Notre Dame
Center for Nano Science
and Technology

Under development

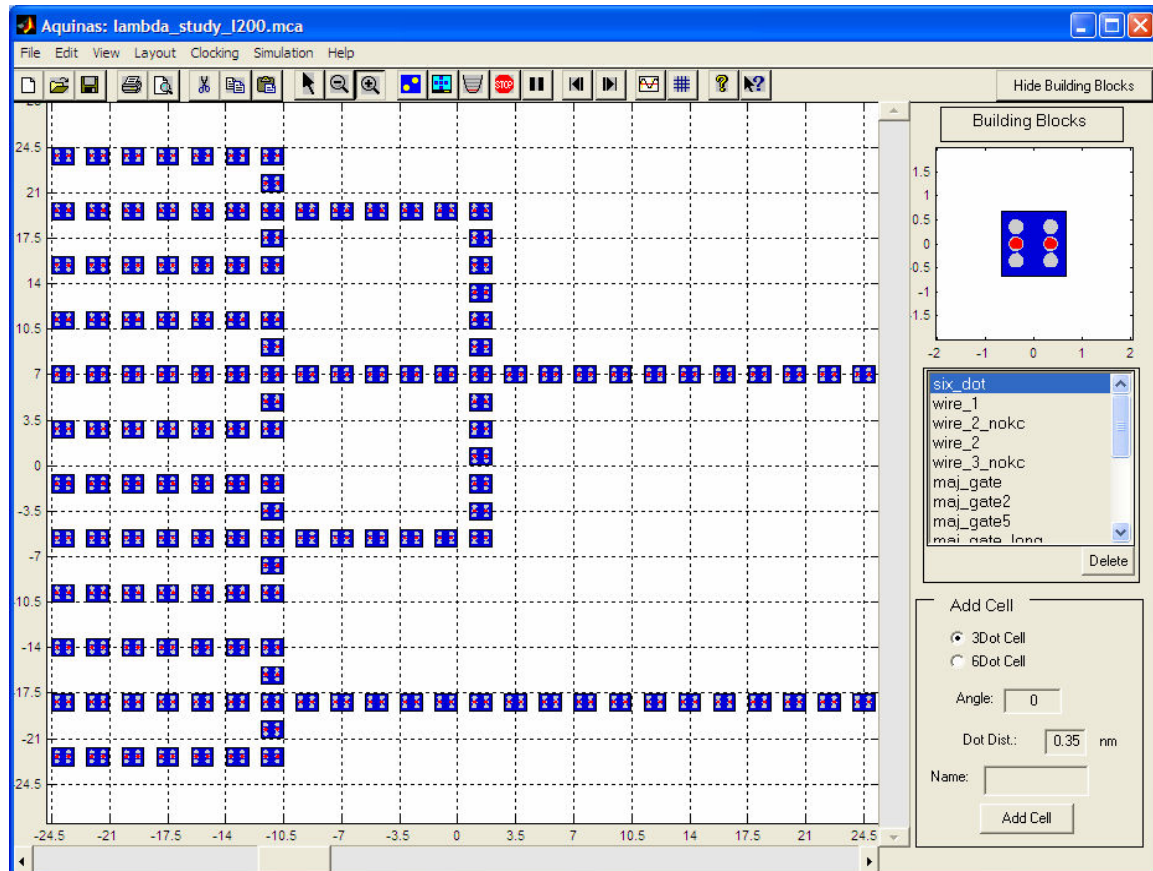




M-AQUINAS

Molecular version of A QUantum Interconnected Network Array Simulator

- GUI allows point-and-click and drag-and-drop editing of QCA circuits.
- Schrödinger solver coupled to local clocking field.



Notre Dame
Center for Nano Science
and Technology

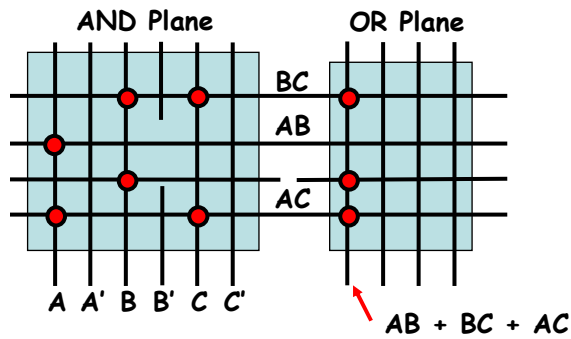
Authors: Enrique Blair
Amy DeCelles



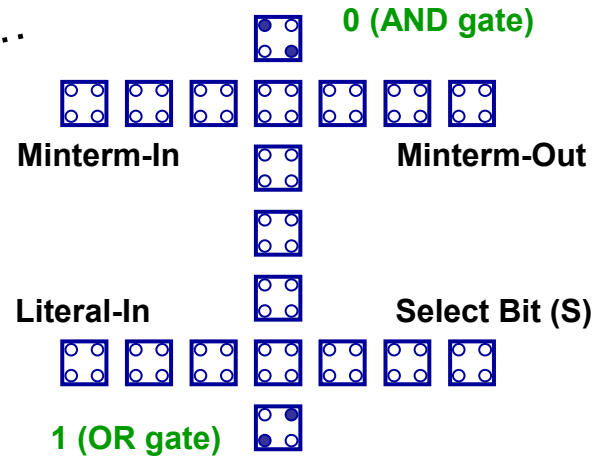


Simulation hierarchies

Architectural-level



+ Logic-level...

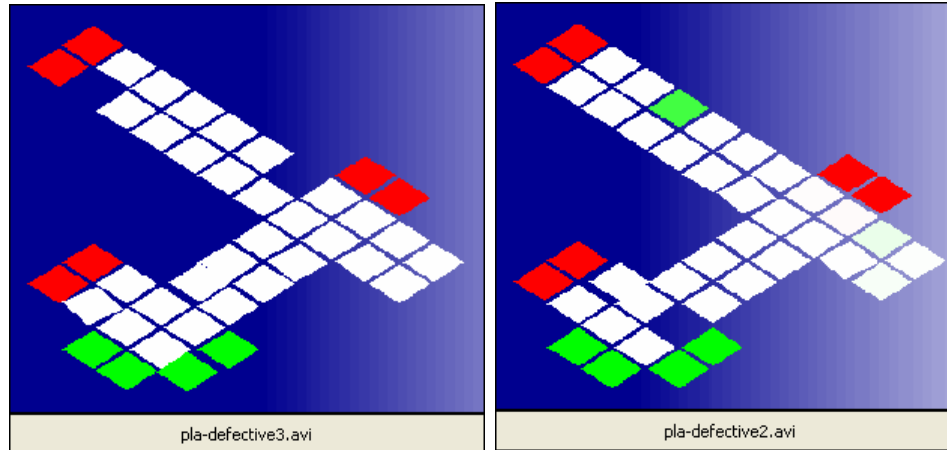


+ device-level...

Minterm-In

Literal-In

Select Bit (S)



=
Application-level
performance
metrics



Notre Dame
Center for Nano Science
and Technology





Conclusions

- **Power is a problem for logic today, and it is related to an approach to thermodynamic limits on computing**
- **However, these limits are due in part to historical choices that can be circumvented**
 - **Requires new basis for logic**
 - **Requires new devices, notably devices that handle information and heat differently**
- **Also: A tie in to coherent quantum computing**



Partnership Opportunity

- **This is a project under NINE and SBET**
 - **We are advocating research in**
 - **Computing beyond the limits of CMOS**
 - **Physics of information processing**
 - **The overall project's deliverables to Sandia are to bootstrap multiple projects in**
 - **Physical science**
 - **Information science**
 - **Simulation**
 - **We've tried to outline opportunity and expose Sandia to willing partners**

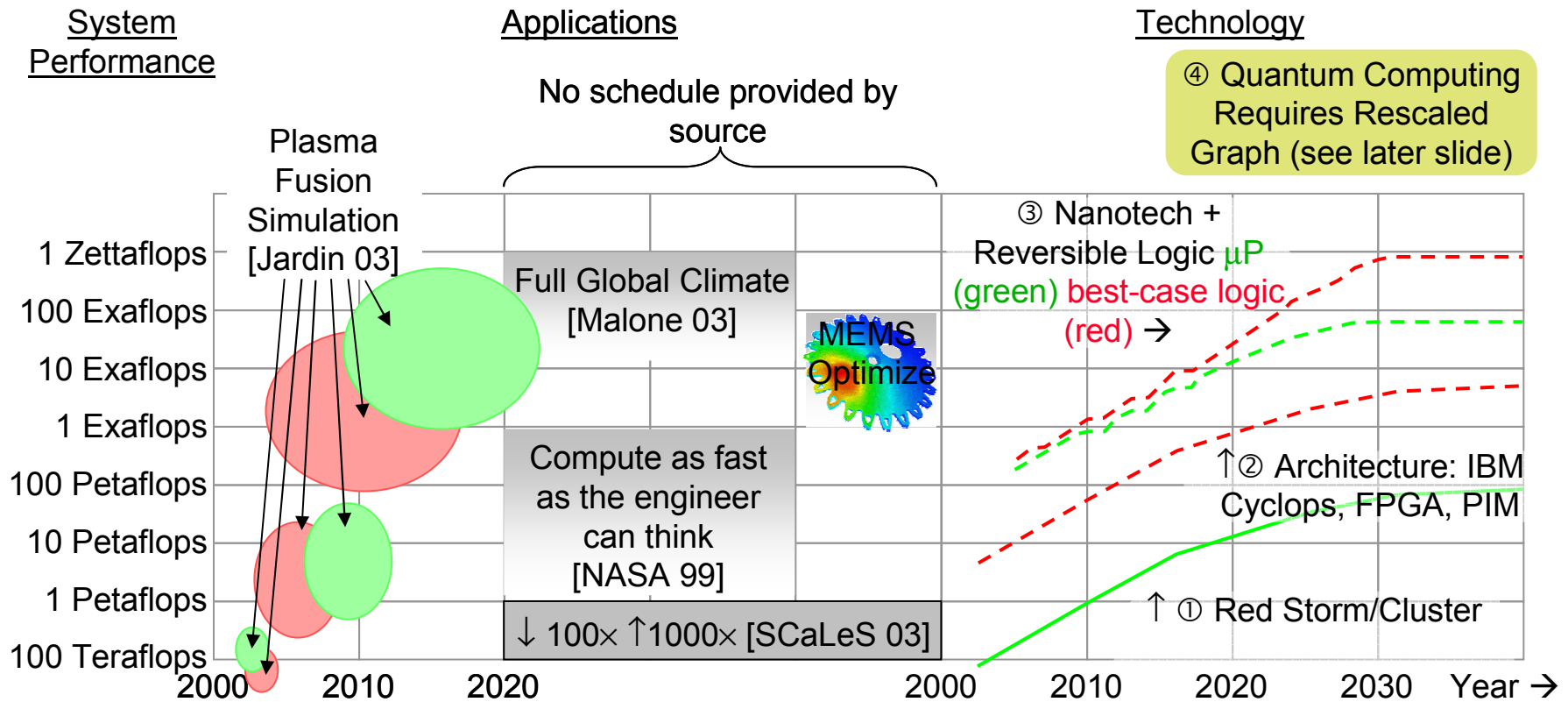


Experiments Under Discussion

- **Continuation of Quantum Fortress work 1100**
- **Molecular QCA 1800**
- **Quantum Computing Tie-In**
 - **Architecture**
 - **Quantum Dot Measurements**
 - **Quantum Dot Manufacturing classical/quantum**
- **Computer Architecture beyond limits of Moore's Law**
- **Simulation of information+Physics**



Applications and \$100M Supercomputers



[Jardin 03] S.C. Jardin, "Plasma Science Contribution to the SCaLeS Report," Princeton Plasma Physics Laboratory, PPPL-3879 UC-70, available on Internet.
 [Malone 03] Robert C. Malone, John B. Drake, Philip W. Jones, Douglas A. Rotman, "High-End Computing in Climate Modeling," contribution to SCaLeS report.
 [NASA 99] R. T. Biedron, P. Mehrotra, M. L. Nelson, F. S. Preston, J. J. Rehder, J. L. Rogers, D. H. Rudy, J. Sobieski, and O. O. Storaasli, "Compute as Fast as the Engineers Can Think!" NASA/TM-1999-209715, available on Internet.
 [SCaLeS 03] Workshop on the Science Case for Large-scale Simulation, June 24-25, proceedings on Internet a <http://www.pnl.gov/scales/>.
 [DeBenedictis 04], Erik P. DeBenedictis, "Matching Supercomputing to Progress in Science," July 2004. Presentation at Lawrence Berkeley National Laboratory, also published as Sandia National Laboratories SAND report SAND2004-3333P. Sandia technical reports are available by going to <http://www.sandia.gov> and accessing the technical library.